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Final

Test Report

P15_0209-
2_017_MagniV_S12ZVL128_L22_Report00
Date of Approval: 2016-Mar-17

Device Under Test

Object Family MC9S12ZVL
Manufacturer Freescale Semiconductor
Type S12ZVL128
Sample marking P9ZV LA12MLF ON37P
CCTCJA

Customer

Order No. P15_0209
Name Freescale Semiconductor Mexico
Address Periférico Sur 8110
Col. El Mante
TLAQUEPAQUE, JALISCO, 45609
MEXICO

Number of Pages

51

Test Period

from ww11/2016 until ww11/2016

Test Method / Test Requirement

LIN Conformance Test Specification

Performed Tests and References

1 LIN OSI Layer 1 – Physical Layer
For LIN devices with Rx and Tx access
For the LIN Physical Layer Specification
Revision 2.2 (Dec. 31th, 2010)
LIN OSI Layer1 Physical Layer for LIN Specification 2.2
Version 2.2

Conformance Test Results

The Test Results refer to the delivered device.

1 LIN OSI Layer 1 for Revision 2.2

Pass

For detailed information see chapter Test List at the following pages.

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Approved by

Test performed by

L. Kukla, Project Manager

J. Eversmeier, Project Engineer

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Revision History

Old revision	New revision	Amendment Description	Editor
–	00	Final version	LK

1 Device Under Test (detailed)

General	
Date of Sample Arrival	26.02.2016
Manufacturer	Freescale Semiconductor
Sample Marking	P9ZV LA12MLF ON37P CCTCJA
Test performed with DUT no.	#1

Device Specification	
Family Name	MC9S12ZVL
Version	S12ZVL128
Design step	-
HW-Version	-
SW-Version	-

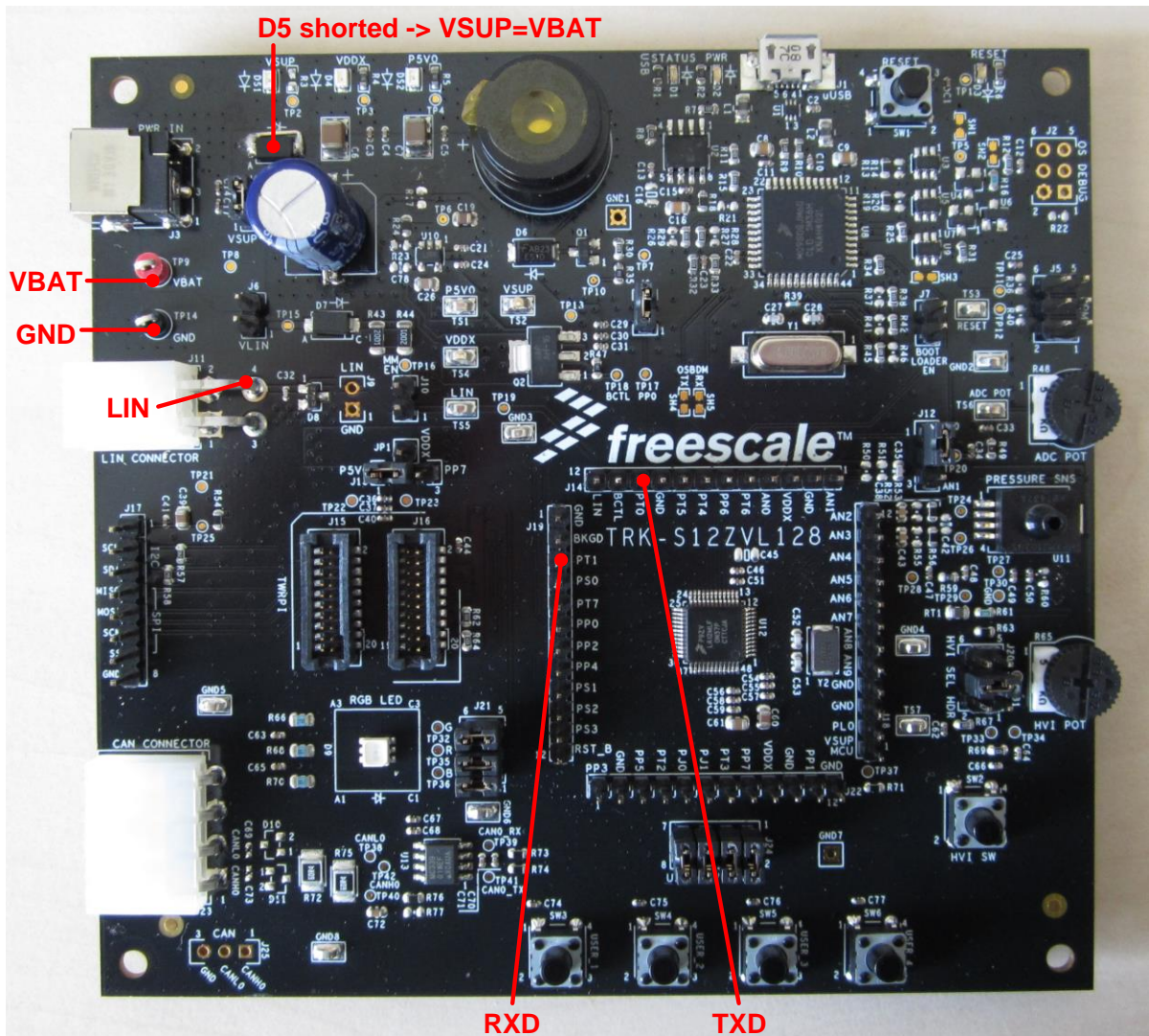
Documentation	
Hardware manual	[DRAFT]_-_TRK-S12ZVL128_QuickStartGuide_05_11_2015.pdf ZVL128_-_ [Preliminary]_Schematic_EVB_-_SPF-28765.pdf
User manual / datasheet	MC9S12ZVL_Rev2.00_Draft_G.pdf

Device Classification	
According to	A+

Software Specification	
IDE	-
Compiler	-
Device	-

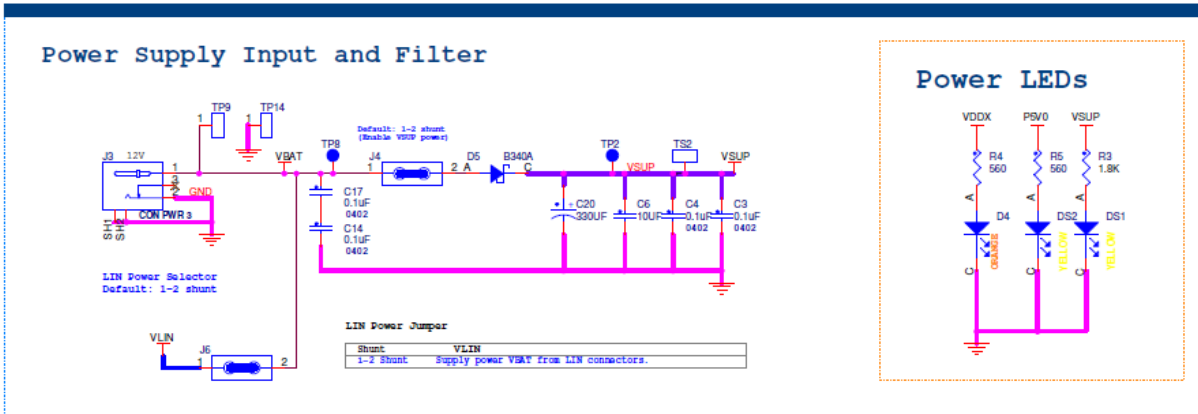
Supplement	
Node Capability File	-
Connection plan	P15_0209- 2_009_MagniV_S12ZVL128_L22_Connection_Plan00.pdf

2 Setup for Device Under Test

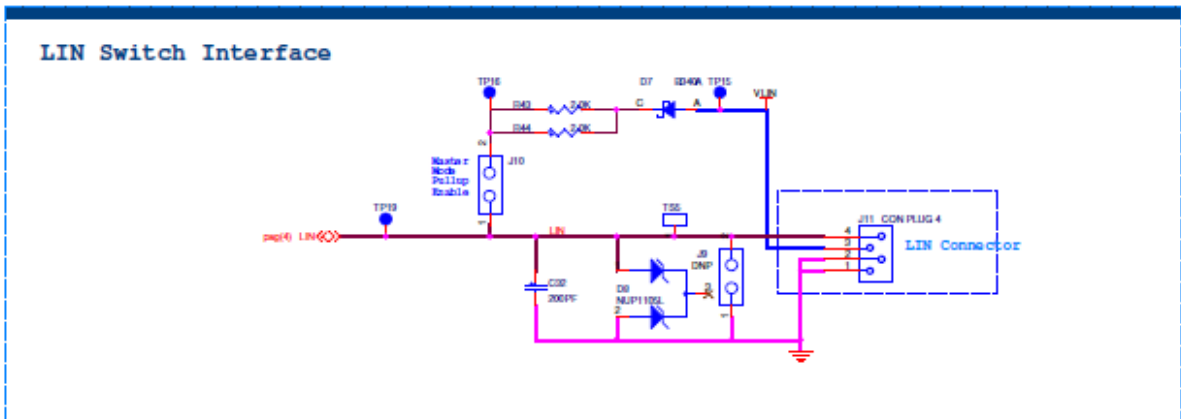


Function	Description
RXD	Internal signal LPRXD was routed to port PT1 (J19 pin 3). PS0 has a push/pull output, no external pull-up resistor required.
TXD	Internal signal LPTXD was routed to port PT0 (J14 pin 10).
LIN	C32 = 200pF Slave node capacitance; D8 = NUP1105L (ESD Diode)
VSUP	VSUP=VBAT; D5 shorted
IO Voltage	VDDX=3.3V
Slew Rate	All Tests were performed with a slew rate optimized for 20kBit/s, except test group 2.5.1. Test group 2.5.1 was performed with a slew rate optimized for 10.4kBit/s.

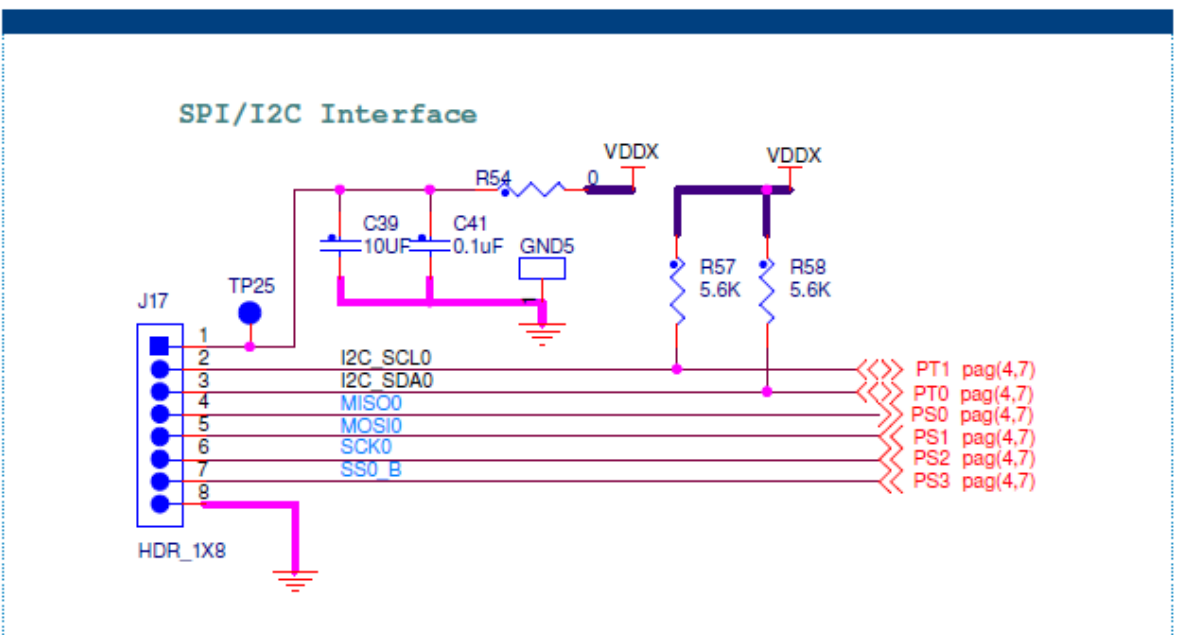
Schematic



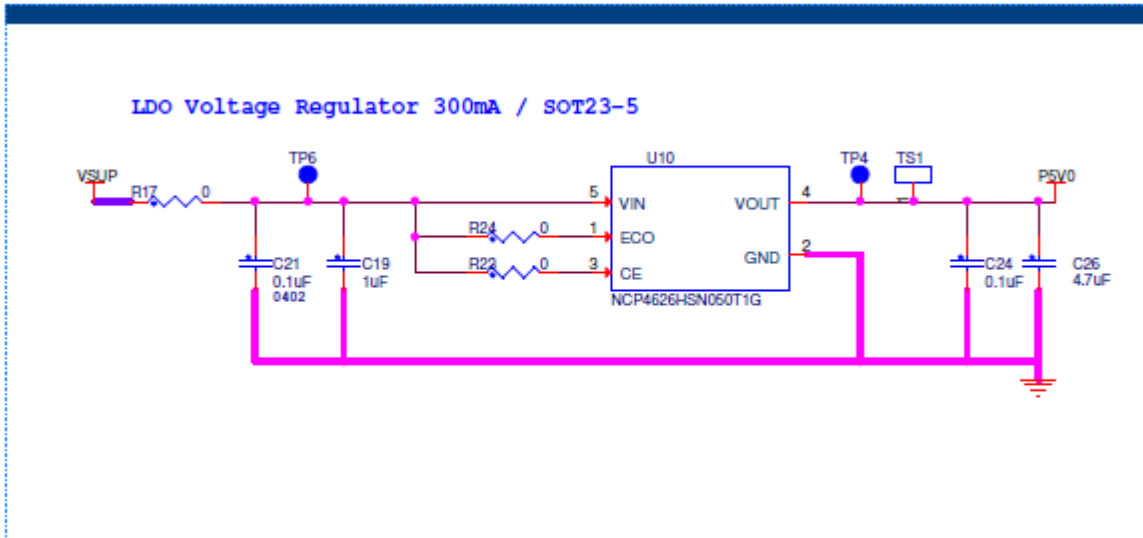
D5 shorted -> VSUP=VBAT; R3 removed; C20 replaced for 50V



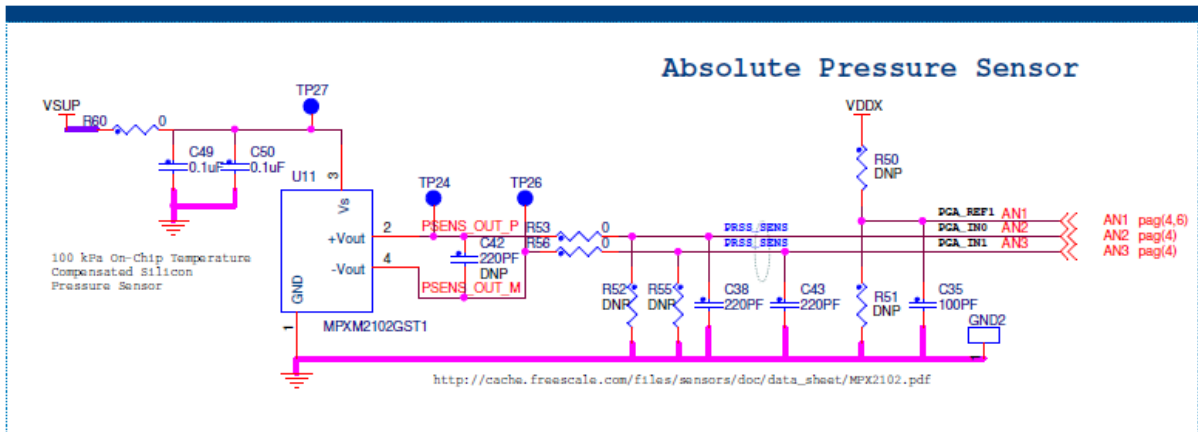
J10 open



PT0 and PT1 are pulled to VDDX with 5.6kΩ

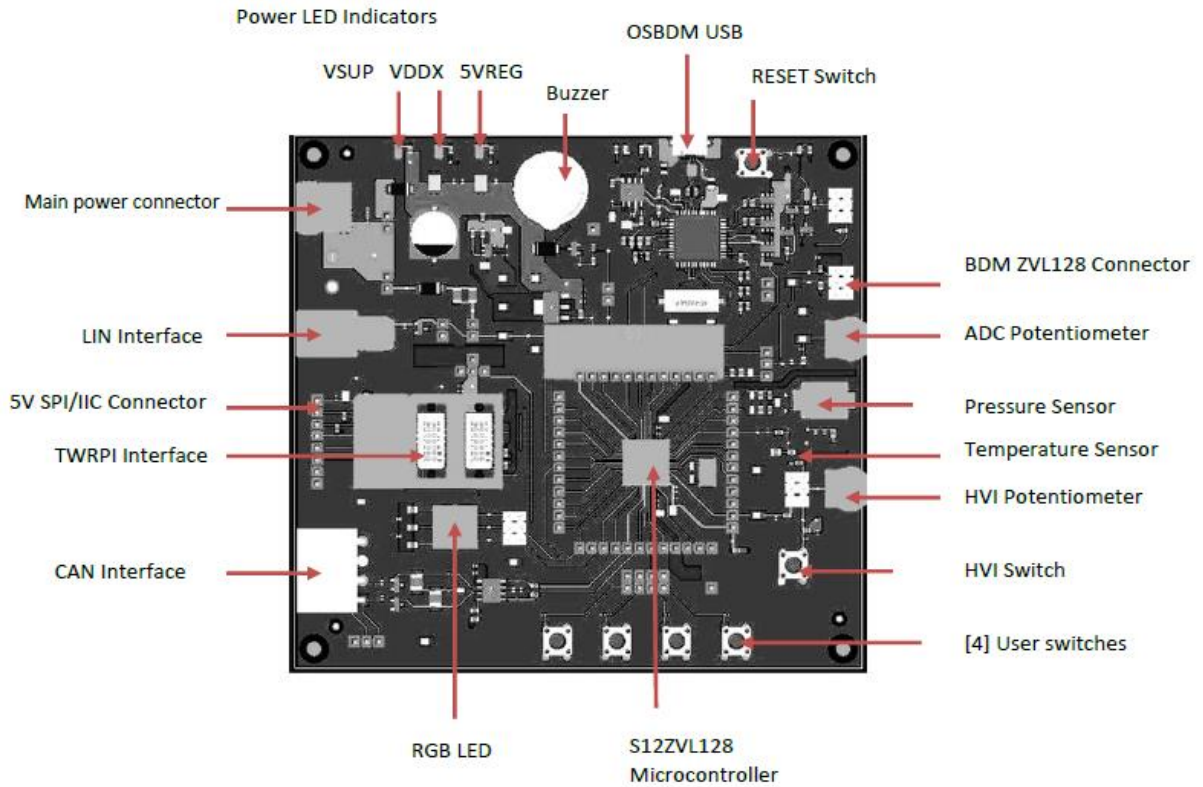


R17 removed

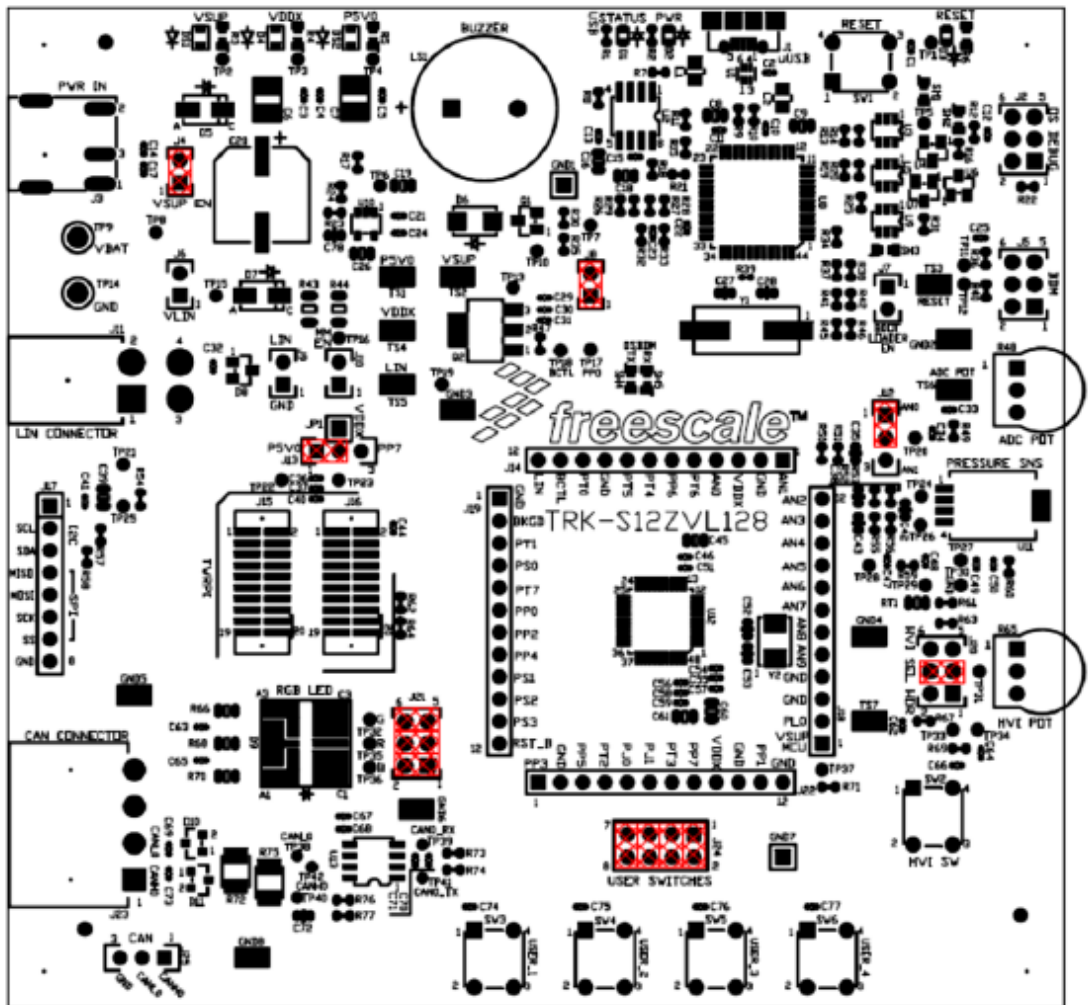


R60 removed

TRK-S12ZVL



Jumper Configuration Diagram



3 Test Equipment

The following test equipment and test system have been used.

No.	Component	Manufacturer	Version / Type	ID
C&S Hardware				
LIN 2.2				
1	LIN-Power switch Board	C&S	Rev 2.1	CSHW_000037
2	LIN-Stimulation Board	C&S	Rev 2.2	CSHW_000096
3	LIN-GND-shift Board	C&S	Rev 1.3	CSHW_000075
4	LIN-IUT Board	C&S	Rev 2.1	CSHW_000071
5	LIN-Adapter Board	C&S	Rev 2.2	CSHW_000097
6	LIN-Adapter Board	C&S	Rev 2.2	CSHW_000073
7	LIN-Adapter Board	C&S	Rev 1.1	CSHW_000040
8	LIN-Adapter Board	C&S	Rev 1.1	CSHW_000099
9	LIN Stimuli Board	C&S	Rev.1.2	CSHW_000010
10	LIN IUT Board	C&S	Rev 2.1	CSHW_000193
LIN ext. Duty Cycle Test				
11	Duty Cycle Board	C&S	Rev 1.0	CSHW_000212
Test System Hardware				
12	Power Supply	Hameg	HM 8142	CS140142
13	Power Supply	Hameg	HM 8142	700013
14	Power Supply	Hameg	HM 8142	CS140220
15	Oscilloscope	Agilent	54622D	700035
16	Oscilloscope	Agilent	MSO8104A	700090
17	Function/ Waveform generator	Hewlett Packard	33120A	700007
18	Function/ Waveform generator	Hewlett Packard	33120A	700043
19	Data Acquisition /Switch Unit	Agilent	34970A	CS140147
20	Data Acquisition /Switch Unit	Agilent	34970A	CS140146
21	20-Channel-Multiplexer Module (2/4 Wire)	Agilent	34901A	700096
22	20-Channel-Multiplexer Module (2/4 Wire)	Agilent	34901A	700095
23	20-Channel Actuator Module	Agilent	34903A	CS140145
Software				
24	LIN_PL_Supervisor	C&S	1.0.5.0, Build 5	

4 Technical Correspondence

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5 Test List

5.1 Dynamic Tests

Following test case numeration relates on the corresponding test specification

No.	Description	Result	Comment
2.1	Operating Voltage Range		
2.1.1	Voltage Ramp $V_{SUP} = [7V...18V]$, 0.1V/s [up]	Pass	RX shows the 10kHz Signal, The maximum deviation is less or equal than 10%
2.1.2	Voltage Ramp $V_{SUP} = [18V...7V]$, 0.1V/s [down]	Pass	RX shows the 10kHz Signal, The maximum deviation is less or equal 10%
2.2	Threshold Voltages		
2.2.1	IUT as Receiver: V_{SUP} @ V_{BUS_DOM} (down)		
2.2.1.1	$V_{SUP} = 7V$ Signal Range [18V...4.2V] Expected RX Signal recessive	Pass	RX is recessive.
	$V_{SUP} = 7V$ Signal Range [2.8V...-1.05V] Expected RX Signal dominant	Pass	RX is dominant.
2.2.1.2	$V_{SUP} = 13V$ Signal Range [18V...7.8V] Expected RX Signal recessive	Pass	RX is recessive.
	$V_{SUP} = 13V$ Signal Range [5.2V...-2.1V] Expected RX Signal dominant	Pass	RX is dominant.
2.2.1.3	$V_{SUP} = 18V$ Signal Range [20.7V...10.8V] Expected RX Signal recessive	Pass	RX is recessive.
	$V_{SUP} = 18V$ Signal Range [7.2V...-2.7V] Expected RX Signal dominant	Pass	RX is dominant.
2.2.2	IUT as Receiver: V_{SUP} @ V_{BUS_REC} (up)		
2.2.2.1	$V_{SUP} = 7V$ Signal Range [-1.05V...2.8V] Expected RX Signal dominant	Pass	RX is dominant.
	$V_{SUP} = 7V$ Signal Range [4.2V...18V] Expected RX Signal recessive	Pass	RX is recessive.
2.2.2.2	$V_{SUP} = 13V$ Signal Range [-2.1V...5.2V] Expected RX Signal dominant	Pass	RX is dominant.
	$V_{SUP} = 13V$ Signal Range [7.8V...18V] Expected RX Signal recessive	Pass	RX is recessive.

No.	Description	Result	Comment
2.2.2.3	$V_{SUP} = 18V$ Signal Range [-2.7V...7.2V] Expected RX Signal dominant	Pass	RX is dominant.
	$V_{SUP} = 18V$ Signal Range [10.8V...20.7V] Expected RX Signal recessive	Pass	RX is recessive.
2.2.3	IUT as Receiver: V_{SUP} @ V_{BUS}		
2.2.3.1	$V_{SUP} = 7V$ Signal Range [-1.05V...8.05V] up [8.05V...-1.05V] down	Pass	V_{BUS_CNT} is in range of $[0.475...0.525]*V_{SUP}$, V_{HYS} is less than $0.175*V_{SUP}$.
2.2.3.2	$V_{SUP} = 14V$ Signal Range [-2.1V...16.1V] up [16.1V...-2.1V] down	Pass	V_{BUS_CNT} is in range of $[0.475...0.525]*V_{SUP}$, V_{HYS} is less than $0.175*V_{SUP}$.
2.2.3.3	$V_{SUP} = 18V$ Signal Range [-2.7V...20.7V] up [20.7V...-2.7V] down	Pass	V_{BUS_CNT} is in range of $[0.475...0.525]*V_{SUP}$, V_{HYS} is less than $0.175*V_{SUP}$.
2.3	Variation of $V_{SUP_NON_OP} \in [-0.3V \dots 7.0V]$; [18V ... 40V]		
2.3.1	Master ECU $V_{BAT} = [-0.3V...8V]$, [18V...40V] 60 k Ω + diode to $V_{LIN} = 18V$	Not applicable	IUT as Transceiver
2.3.2	Slave ECU $V_{BAT} = [-0.3V...8V]$, [18V...40V] 1.1k Ω + diode to $V_{LIN} = 18V$	Not applicable	IUT as Transceiver
2.3.3	Transceiver $V_{SUP} = [-0.3V...7V]$, [18V...40V] 1.1 k Ω + diode to $V_{LIN} = 18V$	Pass	No dominant state occurs, the IUT is not destroyed, the recessive voltage afterwards is less or equal +/-5%
2.4	I_{BUS} Under Several Conditions		
2.4.1	I_{BUS_LIM} @ Dominant State (Driver On); $V_{IUT} = 18V$	Pass	LIN shows the rectangular signal, the dominant state bus level is lower than $th_dom=4.518V$ for Transceiver
2.4.2	$I_{BUS_PAS_dom}$: IUT in Recessive State : $V_{IUT} = 12V$; $V_{BUS} = 0V$	Pass	The maximum voltage drop is higher than -500mV.
2.4.3	$I_{BUS_PAS_rec}$: IUT in Recessive State : $V_{SUP} = 7V$ with Variation of $V_{BUS} \in [8V \dots 18V]$	Pass	The maximum voltage drop is less or equal than 20mV.

No.	Description	Result	Comment
2.5	Slope Control		
2.5.1	Measuring the Duty Cycle @ 10.4 kBit/sec – IUT as Transmitter		
2.5.1.1.1	$V_{SUP} = 7V$ Bus Load = 1nF, 1k Ω $V_{PS2}=6.0V$	Pass	The measured duty cycle D3 is greater or equal than 0.417.
2.5.1.1.2	$V_{SUP} = 7V$ Bus Load = 1nF, 1k Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417.
2.5.1.2.1	$V_{SUP} = 7V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=6.0V$	Pass	The measured duty cycle D3 is greater or equal than 0.417.
2.5.1.2.2	$V_{SUP} = 7V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417.
2.5.1.3.1	$V_{SUP} = 7V$ Bus Load = 10nF, 500 Ω $V_{PS2}=6.0V$	Pass	The measured duty cycle D3 is greater or equal than 0.417.
2.5.1.3.2	$V_{SUP} = 7V$ Bus Load = 10nF, 500 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417.
2.5.1.4.1	$V_{SUP} = 7.6V$ Bus Load = 1nF, 1k Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.4.2	$V_{SUP} = 7.6V$ Bus Load = 1nF, 1k Ω $V_{PS2}=7.2V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.5.1	$V_{SUP} = 7.6V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.5.2	$V_{SUP} = 7.6V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=7.2V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.

No.	Description	Result	Comment
2.5.1.6.1	$V_{SUP} = 7.6V$ Bus Load = 10nF, 500 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.6.2	$V_{SUP} = 7.6V$ Bus Load = 10nF, 500 Ω $V_{PS2}=7.2V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.7.1	$V_{SUP} = 18V$ Bus Load = 1nF, 1k Ω $V_{PS2}=17.0V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.7.2	$V_{SUP} = 18V$ Bus Load = 1nF, 1k Ω $V_{PS2}=17.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.8.1	$V_{SUP} = 18V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=17.0V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.8.2	$V_{SUP} = 18V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=17.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.9.1	$V_{SUP} = 18V$ Bus Load = 10nF, 500 Ω $V_{PS2}=17.0V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.
2.5.1.9.2	$V_{SUP} = 18V$ Bus Load = 10nF, 500 Ω $V_{PS2}=17.6V$	Pass	The measured duty cycle D3 is greater or equal than 0.417, the measured duty cycle D4 is less or equal than 0.590.

No.	Description	Result	Comment
2.5.2	Measuring the Duty Cycle @ 20.0 kBit/sec – IUT as Transmitter		
2.5.2.1.1	$V_{SUP} = 7V$ Bus Load = 1nF, 1k Ω $V_{PS2}=6.0V$	Pass	The measured duty cycle D1 is greater or equal than 0.396.
2.5.2.1.2	$V_{SUP} = 7V$ Bus Load = 1nF, 1k Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D1 is greater or equal than 0.396.
2.5.2.2.1	$V_{SUP} = 7V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=6.0V$	Pass	The measured duty cycle D1 is greater or equal than 0.396.
2.5.2.2.2	$V_{SUP} = 7V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D1 is greater or equal than 0.396.
2.5.2.3.1	$V_{SUP} = 7V$ Bus Load = 10nF, 500 Ω $V_{PS2}=6.0V$	Pass	The measured duty cycle D1 is greater or equal than 0.396.
2.5.2.3.2	$V_{SUP} = 7V$ Bus Load = 10nF, 500 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D1 is greater or equal than 0.396.
2.5.2.4.1	$V_{SUP} = 7.6V$ Bus Load = 1nF, 1k Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.4.2	$V_{SUP} = 7.6V$ Bus Load = 1nF, 1k Ω $V_{PS2}=7.2V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.5.1	$V_{SUP} = 7.6V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.5.2	$V_{SUP} = 7.6V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=7.2V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.

No.	Description	Result	Comment
2.5.2.6.1	$V_{SUP} = 7.6V$ Bus Load = 10nF, 500 Ω $V_{PS2}=6.6V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.6.2	$V_{SUP} = 7.6V$ Bus Load = 10nF, 500 Ω $V_{PS2}=7.2V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.7.1	$V_{SUP} = 18V$ Bus Load = 1nF, 1k Ω $V_{PS2}=17.0V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.7.2	$V_{SUP} = 18V$ Bus Load = 1nF, 1k Ω $V_{PS2}=17.6V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.8.1	$V_{SUP} = 18V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=17.0V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.8.2	$V_{SUP} = 18V$ Bus Load = 6.8nF, 660 Ω $V_{PS2}=17.6V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.9.1	$V_{SUP} = 18V$ Bus Load = 10nF, 500 Ω $V_{PS2}=17.0V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.
2.5.2.9.2	$V_{SUP} = 18V$ Bus Load = 10nF, 500 Ω $V_{PS2}=17.6V$	Pass	The measured duty cycle D1 must be greater or equal than 0.396, the measured duty cycle D2 is less or equal 0.581.

No.	Description	Result	Comment
2.6	Propagation Delay		
2.6.1	Propagation Delay of the Receiver		
2.6.1.1	V _{SUP} = 7V RX Load = 20pF	Pass	t _{rx_pd} is less than 6μs, t _{rx_sym} is in range +/- 2μs.
2.6.1.2	V _{SUP} = 14V RX Load = 20pF	Pass	t _{rx_pd} is less than 6μs, t _{rx_sym} is in range +/- 2μs.
2.6.1.3	V _{SUP} = 18V RX Load = 20pF	Pass	t _{rx_pd} is less than 6μs, t _{rx_sym} is in range +/- 2μs.
2.7	GND / VBAT Shift Test – Dynamic		
2.7.1	GND Shift Test – Dynamic – IUT as Transceiver (Master)	Pass	The duty cycle of RX is in range D1 – 2μs ... D2 + 2μs.
2.7.2	GND Shift Test – Dynamic – IUT as Transceiver (Slave)	Pass	The duty cycle of RX is in range D1 – 2μs ... D2 + 2μs.
2.7.3	VBAT Shift Test – Dynamic – IUT as Transceiver (Master)	Pass	The duty cycle of RX is in range D1 – 2μs ... D2 + 2μs.
2.7.4	VBAT Shift Test – Dynamic – IUT as Transceiver (Slave)	Pass	The duty cycle of RX is in range D1 – 2μs ... D2 + 2μs.
2.8	Failure		
2.8.1	Loss of Battery	Pass	No parasitic current path is formed between the bus line and the DUT.
2.8.2	Loss of GND	Pass	No parasitic current path is formed between the bus line and the DUT.
2.9	Verifying internal capacitance and dynamic interference – IUT as Slave		
2.9.1	Normal power supply	Pass	C _{SLAVE} is less or equal than 250pF: T _{INT} ≤ T _{REF} The IUT does not interfere with the dynamic stimulus

No.	Description	Result	Comment
2.9.2	IUT loss of GND	Pass	C_{SLAVE} is less or equal than 250pF: $T_{INT} \leq T_{REF}$ The IUT does not interfere with the dynamic stimulus
2.9.2	IUT loss of V_{SUP}	Pass	C_{SLAVE} is less or equal than 250pF: $T_{INT} \leq T_{REF}$ The IUT does not interfere with the dynamic stimulus

5.2 Static Tests

The motivation of static test cases is to check the availability and the boundaries in the data sheet of the IUT.

For all integrated circuits every related parameter in Table 4.1 must be part of the data sheet and fulfil the specified boundaries in terms of physical worst case condition. Data sheet parameter names may deviate from the names in Table 4.1, but in this case a cross-reference list (data sheet versus Table 4.1) shall be provided for this test. Parameter conditions may deviate from the conditions in Table 4.1, if the data sheet conditions are according to the physical worst case context in Table 4.1 at least.

If one parameter does not pass this test, the result of the whole conformance test is failed.

Reference LIN Physical Layer Spec Revision 2.2 December 31, 2010, section Line Driver/Receiver, 6.5.4 ELECTRICAL DC PA-RAMETERS, table 6.6 to 6.11

Used data sheets:

MC9S12ZVL_Rev2.00_Draft_G.pdf (reference indicated with 'Ref 1')

Notes to the following table:

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
1.	Param 9	V _{BAT}	8.0	18.0	V	ECU operating voltage	all devices with integrated reverse polarity diode	-
-	DS Items						reference	pass/fail/ comment

Annotations:

- A grey box above the table contains the text "name of parameter and values in LIN specification". Blue arrows point from this box to the "reference", "param.", "min", "max", and "unit" columns of the first row.
- A red box above the table contains the text "cross reference". A red arrow points from this box to the "comment/condition" cell of the first row.
- A grey box below the table contains the text "Name/values of parameter in data sheet". Blue arrows point from this box to the "reference", "param.", "min", "max", and "unit" columns of the first row.
- A grey box below the table contains the text "Reference to place/passage in document". A blue arrow points from this box to the "valid for, reference" cell of the second row.
- A red oval highlights the "reference", "param.", "min", "max", and "unit" columns of the first row.

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
1.	Param 9	V_{BAT}	8.0	18.0	V	ECU operating voltage	all devices with integrated reverse polarity diode	-
-		-	-	-	-	-	-	Not applicable, no diode
2.	Param 10	V_{SUP}	7.0	18.0	V	Supply voltage range	all devices without integrated reverse polarity diode	-
-		V_{LINSUP_LIN}	5.5	18	V	V_{LINSUP} operating range	Ref1 Page 710 Table D-2 Num 1	Pass
3.	Param 11	$V_{SUP_NON_OP}$	-0.3	40.0	V	voltage range within which the device is not destroyed	all devices	-
-		V_{SUP}	-0.3	42	V	Voltage regulator and LINPHY supply voltage	Ref1 Page 684 Table A-3 Num 1	Pass
4.	Param 12	I_{BUS_LIM}	40	200	mA	Current Limitation for Driver dominant state driver on $V_{BUS} = V_{BAT_max}$	all devices with integrated LIN transmitter	-
-		I_{LIN_LIM}	40	200	mA	Current limitation into the LIN pin in dominant state ⁴ $V_{LIN} = V_{LINSUP_LIN_MAX}$	Ref1 Page 710 Table D-2 Num 2	Pass
5.	Param 13	$I_{BUS_PAS_dom}$	-1		mA	Input Leakage Current at the Receiver incl. Slave Pull-Up Resistor as specified in Table 6.7 driver off $V_{BUS} = 0V$ $V_{BAT} = 12V$	all devices with integrated slave pull-up resistor	-
-		$I_{LIN_PAS_dom}$	-1		mA	Input leakage current in dominant state, driver off, internal pull-up on $V_{LIN} = 0V, V_{LINSUP} = 12V$	Ref1 Page 710 Table D-2 Num 3	Pass

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
6.	Param 14	$I_{BUS_PAS_rec}$		20	μA	driver off $8V < V_{BAT} < 18V$ $8V < V_{BUS} < 18V$ $V_{BUS} > V_{BAT}$	all devices	-
-		$I_{LIN_PAS_rec}$		20	μA	Input leakage current in recessive state, driver off $5.5V < V_{LINSUP} < 18V$, $5.5V < V_{LIN} < 18V$, $V_{LIN} > V_{LINSUP}$	Ref1 Page 710 Table D-2 Num 4	Pass
7.	Param 15	$I_{BUS_NO_GND}$	-1	1	mA	Control unit disconnected from ground $GND_{Device} = V_{SUP}$ $0V < V_{BUS} < 18V$ $V_{BAT} = 12V$ Loss of local ground must not affect communication in the residual network.	all devices	-
-		$I_{LIN_NO_GND}$	-1	1	mA	Input leakage current when ground disconnected $GND_{Device} = V_{LINSUP}$, $0V < V_{LIN} < 18V$, $V_{LINSUP} = 12V$	Ref1 Page 710 Table D-2 Num 5	Pass
8.	Param 16	$I_{BUS_NO_BAT}$		100	μA	V_{BAT} disconnected $V_{SUP_Device} = GND$ $0 < V_{BUS} < 18V$ Node has to sustain the current that can flow under this condition. Bus must remain operational under this condition.	all devices	-
-		$I_{LIN_NO_BAT}$		30	μA	Input leakage current when battery disconnected $V_{LINSUP} = GND_{Device}$, $0 < V_{LIN} < 18V$	Ref1 Page 710 Table D-2 Num 6	Pass

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
9.	Param 17	V_{BUSdom}		0.4	V_{SUP}	receiver dominant state	all devices with integrated LIN receiver	-
-		V_{LINdom}		0.4	V_{LINSUP}	Receiver dominant state	Ref1 Page 710 Table D-2 Num 7	Pass
10.	Param 18	V_{BUSrec}	0.6		V_{SUP}	receiver recessive state	all devices with integrated LIN receiver	-
-		V_{LINrec}	0.6		V_{LINSUP}	Receiver recessive state	Ref1 Page 710 Table D-2 Num 8	Pass
11.	Param 19	V_{BUS_CNT}	0.475	0.525	V_{SUP}	$V_{BUS_CNT} = (V_{th_dom} + V_{th_rec})/2$	all devices with integrated LIN receiver	-
-		V_{LIN_CNT}	0.475	0.525	V_{LINSUP}	$V_{LIN_CNT} = (V_{th_dom} + V_{th_rec})/2$	Ref1 Page 710 Table D-2 Num 9	Pass
12.	Param 20	V_{HYS}		0.175	V_{SUP}	$V_{HYS} = V_{th_rec} - V_{th_dom}$	all devices with integrated LIN receiver	-
-		V_{HYS}		0.175	V_S	$V_{HYS} = V_{th_rec} - V_{th_dom}$	Ref1 Page 710 Table D-2 Num 10	Pass
13.	Param 27	D1	0.396			$T_{HRec(max)} = 0.744 \times V_{SUP}$; $T_{HDom(max)} = 0.581 \times V_{SUP}$; $V_{SUP} = 7.0V...18V$; $t_{Bit} = 50\mu s$; $D1 = t_{Bus_rec(min)} / (2 \times t_{Bit})$	all devices with integrated LIN transmitter D1 valid for 20kBaud	-
-		D1	0.396			Duty cycle 1 $T_{HRec(max)} = 0.744 \times V_{LINSUP}$ $T_{HDom(max)} = 0.581 \times V_{LINSUP}$ $V_{LINSUP} = 5.5V...18V$ $t_{Bit} = 50\mu s$ $D1 = t_{Bus_rec(min)} / (2 \times t_{Bit})$	Ref1 Page 711 Table D-3 Num 7	Pass
14.	Param 28	D2		0.581		$T_{HRec(min)} = 0.422 \times V_{SUP}$; $T_{Hdom(min)} = 0.284 \times V_{SUP}$; $V_{SUP} = 7.6V...18V$; $t_{Bit} = 50\mu s$; $D2 = t_{Bus_rec(max)} / (2 \times t_{Bit})$	all devices with integrated LIN transmitter D2 valid for 20kBaud	-

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
-		D2		0.581		Duty cycle 2 $T_{HRec(min)} = 0.422 \times V_{LINSUP}$ $T_{HDom(min)} = 0.284 \times V_{LINSUP}$ $V_{LINSUP} = 5.5V...18V$ $t_{Bit} = 50\mu s$ $D2 = t_{Bus_rec(max)} / (2 \times t_{Bit})$	Ref1 Page 711 Table D-3 Num 8	Pass
15.	Param 29	D3	0.417			$T_{HRec(max)} = 0.778 \times V_{SUP}$; $T_{HDom(max)} = 0.616 \times V_{SUP}$; $V_{SUP} = 7.0V...18V$; $t_{Bit} = 96\mu s$; $D3 = t_{Bus_rec(min)} / (2 \times t_{Bit})$	all devices with integrated LIN transmitter D3 valid for 10.4 kBaud	-
-		D3	0.417			Duty cycle 3 $T_{HRec(max)} = 0.778 \times V_{LINSUP}$ $T_{HDom(max)} = 0.616 \times V_{LINSUP}$ $V_{LINSUP} = 5.5V...18V$ $t_{Bit} = 96\mu s$ $D3 = t_{Bus_rec(min)} / (2 \times t_{Bit})$	Ref1 Page 712 Table D-3 Num 11	Pass
16.	Param 30	D4		0.590		$T_{HRec(min)} = 0.389 \times V_{SUP}$; $T_{HDom(min)} = 0.251 \times V_{SUP}$; $V_{SUP} = 7.6V...18V$; $t_{Bit} = 96\mu s$; $D4 = t_{Bus_rec(max)} / (2 \times t_{Bit})$	all devices with integrated LIN transmitter D4 valid for 10.4 kBaud	-
-		D4		0.590		Duty cycle 4 $T_{HRec(min)} = 0.389 \times V_{LINSUP}$ $T_{HDom(min)} = 0.251 \times V_{LINSUP}$ $V_{LINSUP} = 5.5V...18V$ $t_{Bit} = 96\mu s$ $D4 = t_{Bus_rec(max)} / (2 \times t_{Bit})$	Ref1 Page 712 Table D-3 Num 12	Pass
17.	Param 31	t_{rx_pd}		6	μs	propagation delay of receiver	all devices with integrated LIN receiver	-
-		t_{rx_pd}		6	μs	Propagation delay of receiver	Ref1 Page 711 Table D-3 Num 3	Pass

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
18.	Param 32	t_{rx_sym}	-2	2	μs	symmetry of receiver propagation delay rising edge w.r.t. falling edge	all devices with integrated LIN receiver	-
-		tr_{x_sym}	-2	2	μs	Symmetry of receiver propagation delay rising edge w.r.t. falling edge	Ref1 Page 711 Table D-3 Num 4	Pass
19.	Param 26	R_{SLAVE}	20	60	$k\Omega$		all devices with integrated slave pull-up resistor	-
-		R_{slave}	27	40	$k\Omega$	Internal pull-up (slave)	Ref1 Page 711 Table D-2 Num 13	Pass
20.	Param 25	R_{MASTER}	900	1100	Ω	The serial diode is mandatory. Only for valid for Transceiver with integrated Master pull up resistor	all devices with integrated master pull-up resistor	-
-		-	-	-	-	-	-	Not applicable No Master
21.	Param 37	C_{SLAVE}		250	pF	Capacitance of slave node	all LIN slave devices	-
-		C_{slave}	220	250	pF	Maximum capacitance allowed on slave node including external components	Ref1 Page 710 Table D-2 Num 11	Pass
22.	LIN 2.2 Specification Chapter 6.5.7	LIN device states changes	-	-	-	All LIN device state changes on conditional events (e.g. temperature shut-down) shall be specified in the LIN device data sheet.	all devices	-
-		t_{OCLIM} t_{DTLIM}	15 16388	16 16389	μs t_{IRC}	Automatic transmitter shutdown in case of an over-current or TxD-dominant timeout	Ref1 Page 32 1.4.1.8 Ref1 Page 711 Table D-3 Num 6 Ref1 Page 711 Table D-3 Num 2	Pass

no.	reference	param.	min	max	unit	comment/condition	valid for, reference	result
23.		LIN transceiver input capacitance	-	-	-	A maximum LIN transceiver input capacitance shall be specified in the LIN device data sheet. Please consider the data sheet limits (e.g. voltage, temperature). The value should be as low as possible.	All devices	-
-		CLIN		45	pF	Capacitance of the LIN pin, Recessive state	Ref1 Page 711 Table D-2 Num 12b	Pass

6 Test Protocol Dynamic Tests

Following test case numeration and cross references relates on the corresponding test specification.

TC 2.1 *Operating Voltage Range*

This test shall ensure the correct operation in the valid supply voltage ranges, by correct reception of dominant bits. The IUT is therefore supplied with an increasing / decreasing voltage ramp.

TC 2.1.1 Voltage Ramp [7.0V...18V], 0.1V/s [up]

Comment	Test Result
The RX pin of the IUT shows the 10kHz signal with a maximum deviation of 10% (time, voltage) is allowed.	Pass

TC 2.1.2 Voltage Ramp [18V...7.0V], 0.1V/s [down]

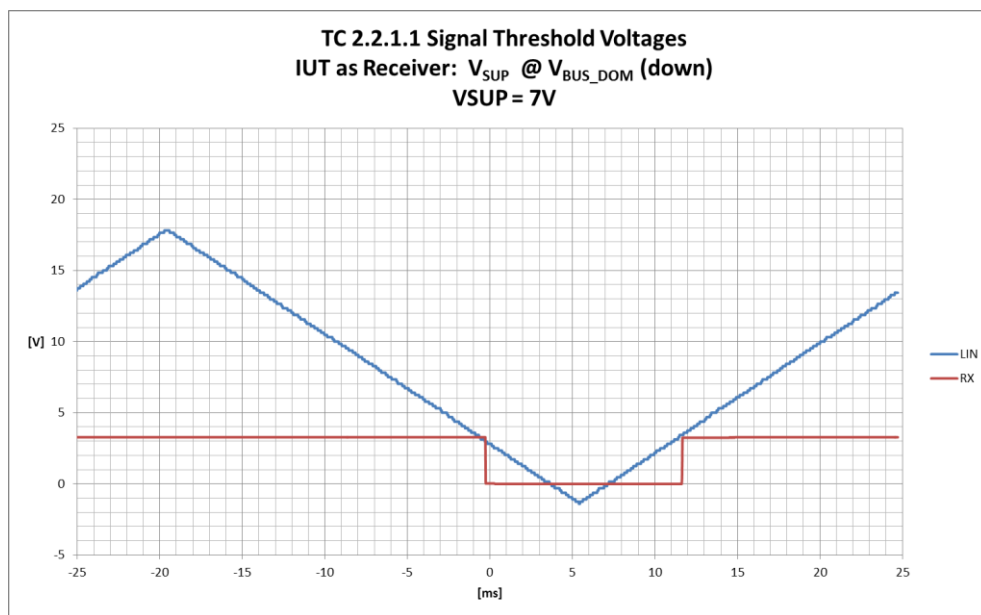
Comment	Test Result
The RX pin of the IUT shows the 10kHz signal with a maximum deviation of 10% (time, voltage) is allowed.	Pass

TC 2.2 Threshold Voltages

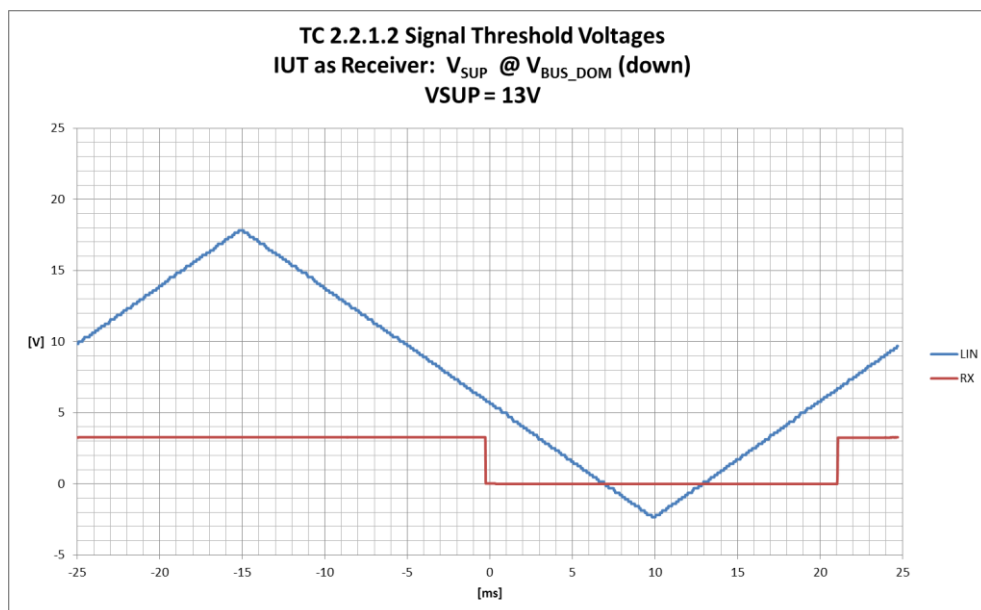
This group of tests checks whether the receiver threshold voltage of the IUT are implemented correctly within the entire specified operating supply voltage range. The LIN Bus voltage is driven with a voltage ramp checking the entire dominant and recessive signal area with respect to the applied supply voltage. In TC 2.2.1 and 2.2.2 the signal has to stay continuously on recessive or dominant level depending on the test case. In TC 2.2.3 the RX output transition is detected.

TC 2.2.1 IUT as Receiver: V_{SUP} @ V_{BUS_DOM} (down)

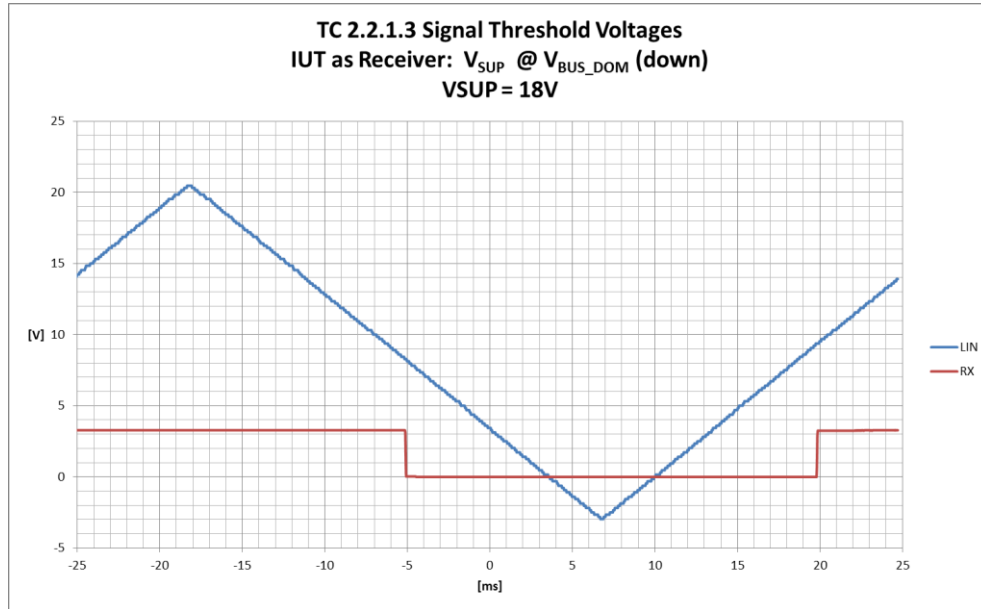
TC 2.2.1.1 $V_{SUP} = 7V$ Signal Range [18V...4.2V], Expected RX Signal recessive
 $V_{SUP} = 7V$ Signal Range [2.8V...-1.05V], Expected RX Signal dominant



TC 2.2.1.2 $V_{SUP} = 13V$, Signal Range [18V...7.8V], Expected RX Signal recessive
 $V_{SUP} = 13V$, Signal Range [5.2 V...-2.1V], Expected RX Signal dominant



TC 2.2.1.3 $V_{SUP} = 18V$, Signal Range [20.7 V...10.8V], Expected RX Signal recessive
 $V_{SUP} = 18V$, Signal Range [7.2 V...-2.7V], Expected RX Signal dominant

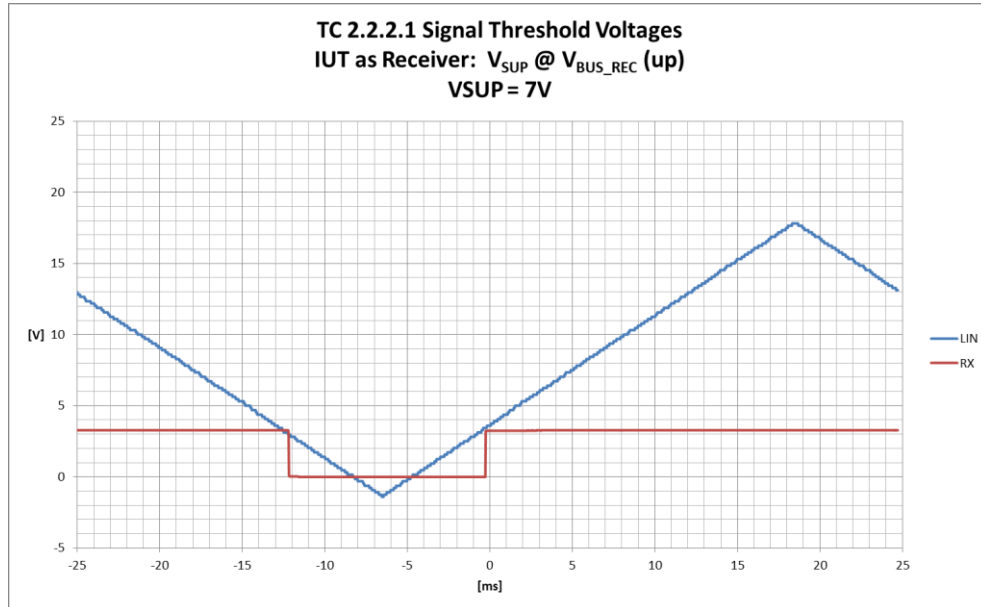


# test	V_{SUP}	Signal Range	Expected RX Signal	Measured RX Signal
2.2.1.1	7V	[18V...4.2V]	recessive	recessive
		[2.8V...-1.05V]	dominant	dominant
2.2.1.2	13V	[18V...7.8V]	recessive	recessive
		[5.2...-2.1V]	dominant	dominant
2.2.1.3	18V	[20.7V...10.8V]	recessive	recessive
		[7.2V...-2.7V]	dominant	dominant

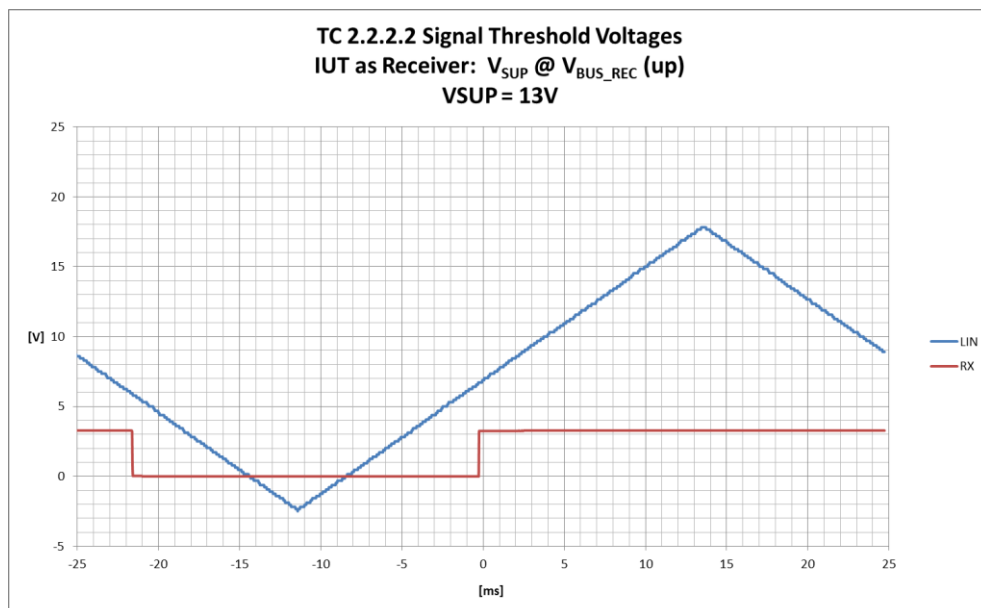
Comment	Test Result
The IUT must generate a dominant or recessive value on RX as defined.	Pass

TC 2.2.2 IUT as Receiver: V_{SUP} @ V_{BUS_REC} (up)

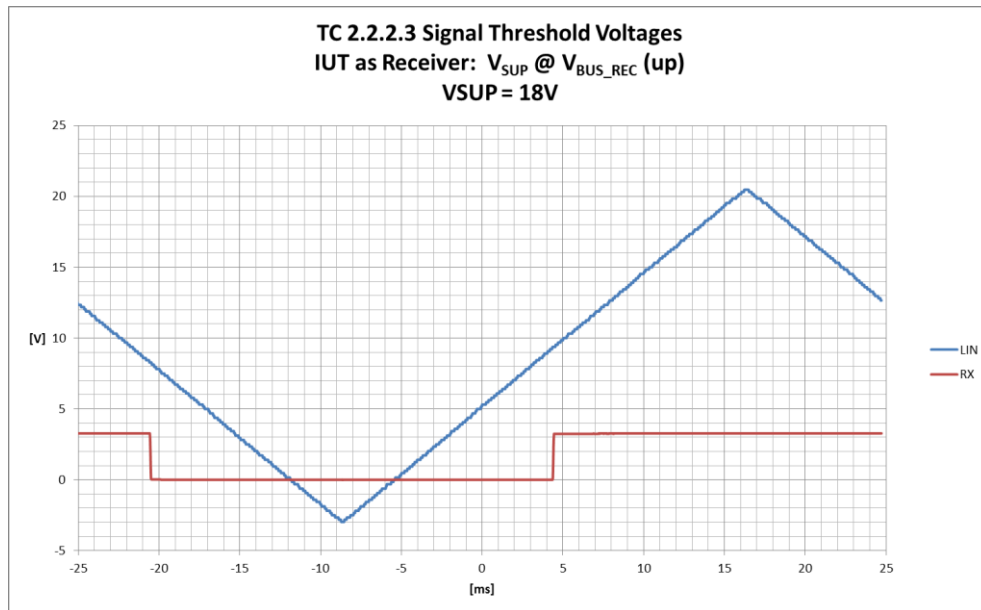
TC 2.2.2.1 $V_{SUP} = 7V$, Signal Range [-1.05V...2.8V], Expected RX Signal dominant
 $V_{SUP} = 7V$, Signal Range [4.2V...18V], Expected RX Signal recessive



TC 2.2.2.2 $V_{SUP} = 13V$, Signal Range [-2.1V...5.2V], Expected RX Signal dominant
 $V_{SUP} = 13V$, Signal Range [7.8V...18V], Expected RX Signal recessive



TC 2.2.2.3 $V_{SUP} = 18V$, Signal Range [-2.7V...7.2V], Expected RX Signal dominant
 $V_{SUP} = 18V$, Signal Range [10.8V...20.7V], Expected RX Signal recessive



# test	V_{SUP}	Signal Range	Expected RX Signal	Measured RX Signal
2.2.2.1	7V	[-1.05V...2.8V]	dominant	dominant
		[4.2V...18V]	recessive	recessive
2.2.2.2	13V	[-2.1V...5.2V]	dominant	dominant
		[7.8...18V]	recessive	recessive
2.2.2.3	18V	[-2.7V...7.2V]	dominant	dominant
		[10.8V...20.7V]	recessive	recessive

Comment	Test Result
The IUT must generate a dominant or recessive value on RX as defined.	Pass

TC 2.2.3 IUT as Receiver: VSUP @ VBUS

This test shall verify the symmetry of the receiver thresholds. For this purpose a voltage ramp on VBUS shows the required threshold values.

TC 2.2.3.1 VSUP = 7V, Signal Range [-1.05V...8.05V] up [8.05V...-1.05V] down

Vsup	7 V
V_th_dom	3.250 V
V_th_rec	3.656 V
V_hys	0.406 V
V_bus_cnt	3.453 V

Comment	Test Result
The RX output transition must meet the following conditions: VBUS_CNT = (Vth_dom+Vth_rec)/2 in range of [0.475...0.525]*VSUP VHYS = Vth_rec – Vth_dom must be less than 0.175*VSUP	Pass

TC 2.2.3.2 VSUP = 14V, Signal Range [-2.1V...16.1V] up [16.1V...-2.1V] down

Vsup	14V
V_th_dom	6.500 V
V_th_rec	7.375 V
V_hys	0.875 V
V_bus_cnt	6.938 V

Comment	Test Result
The RX output transition must meet the following conditions: VBUS_CNT = (Vth_dom+Vth_rec)/2 in range of [0.475...0.525]*VSUP VHYS = Vth_rec – Vth_dom must be less than 0.175*VSUP	Pass

TC 2.2.3.3 VSUP = 18V, Signal Range [-2.7V...20.7V] up [20.7V...-2.7V] down

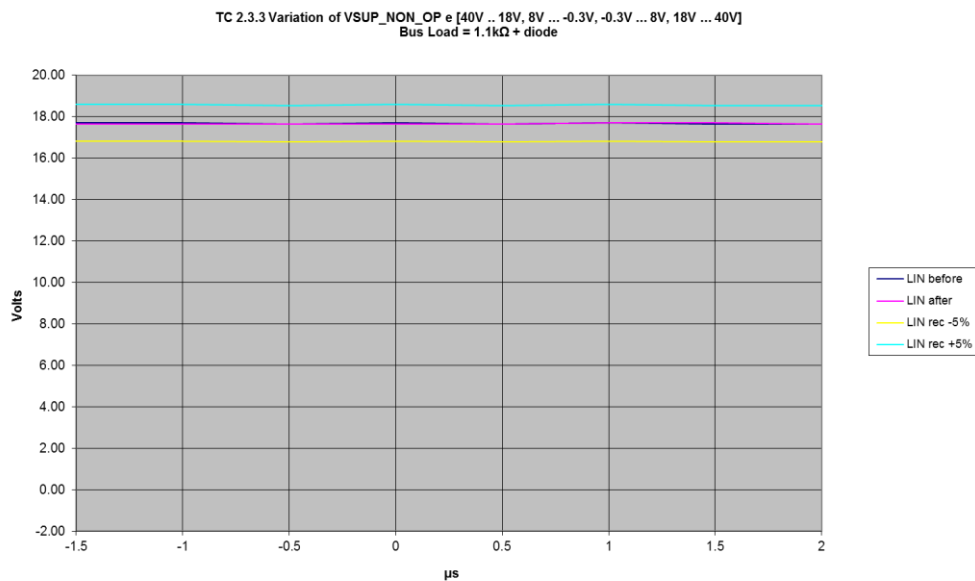
Vsup	18V
V_th_dom	8.375 V
V_th_rec	9.500 V
V_hys	1.125 V
V_bus_cnt	8.938 V

Comment	Test Result
The RX output transition must meet the following conditions: VBUS_CNT = (Vth_dom+Vth_rec)/2 in range of [0.475...0.525]*VSUP VHYS = Vth_rec – Vth_dom must be less than 0.175*VSUP	Pass

TC 2.3 Variation of $V_{SUP_NON_OP} \in [-0.3V...7V], [18V...40V]$

Within this test it should be checked, whether the IUT influences the bus during under and over voltage conditions.

TC 2.3.3 IUT as Transceiver 1.1k Ω + diode to $V_{LIN} = 18 V$

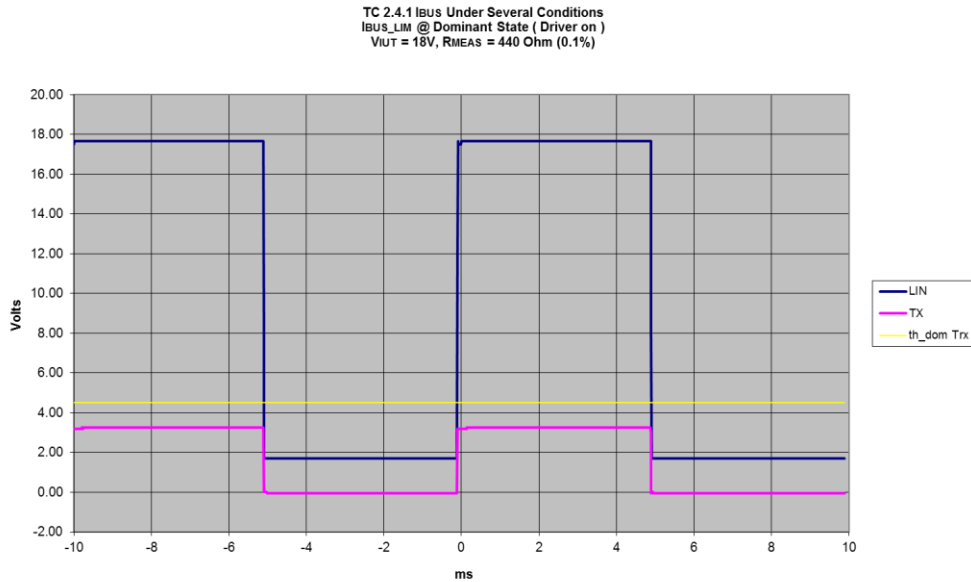


Comment	Test Result
No dominant state on LIN shall occur. The IUT must not be destroyed during the test. The afterwards recessive voltage shall have a maximum deviation of +/-5% from the before recessive voltage.	Pass

TC 2.4 I_{BUS} Under Several Conditions

TC 2.4.1 I_{BUS_LIM} @ Dominant State (Driver On)

This test checks the drive capability of the output stage. A LIN driver has to pull the LIN bus below a certain voltage according to the LIN standard. The current limitation is measured indirectly.



Comment	Test Result
LIN has to show the rectangular signal. The dominant state bus level has to be lower than $th_dom = 4.518V$ for transceiver.	Pass

TC 2.4.2 $I_{BUS_PAS_dom}$: IUT in Recessive State: $V_{BUS} = 0V$

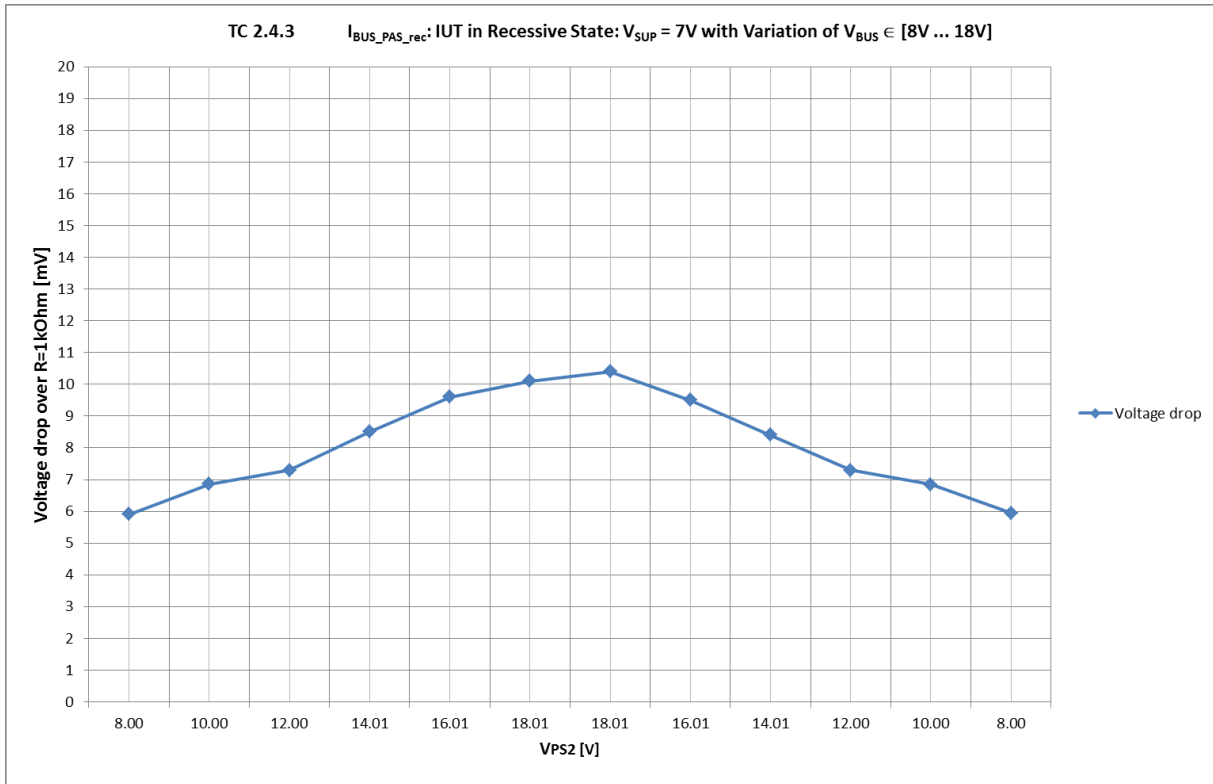
This test case is intended to test the input leakage current $I_{BUS_PAS_dom}$ into a node during dominant state of the LIN bus.

measured Voltage	-164 mV
------------------	---------

Comment	Test Result
The maximum value of voltage drop shall be higher than -500mV.	Pass

TC 2.4.3 $I_{BUS_PAS_rec}$: IUT in Recessive State: $V_{SUP} = 7V$ with Variation of $V_{BUS} \in [8V \dots 18V]$

This test case is checking, whether there is a diode implementation within the termination path of the IUT. The reverse currents should be limited to $I_{BUS_PAS_rec}$ (Max) from the LIN wire into the IUT even if V_{BUS} is higher than the IUT's supply voltage V_{IUT} .

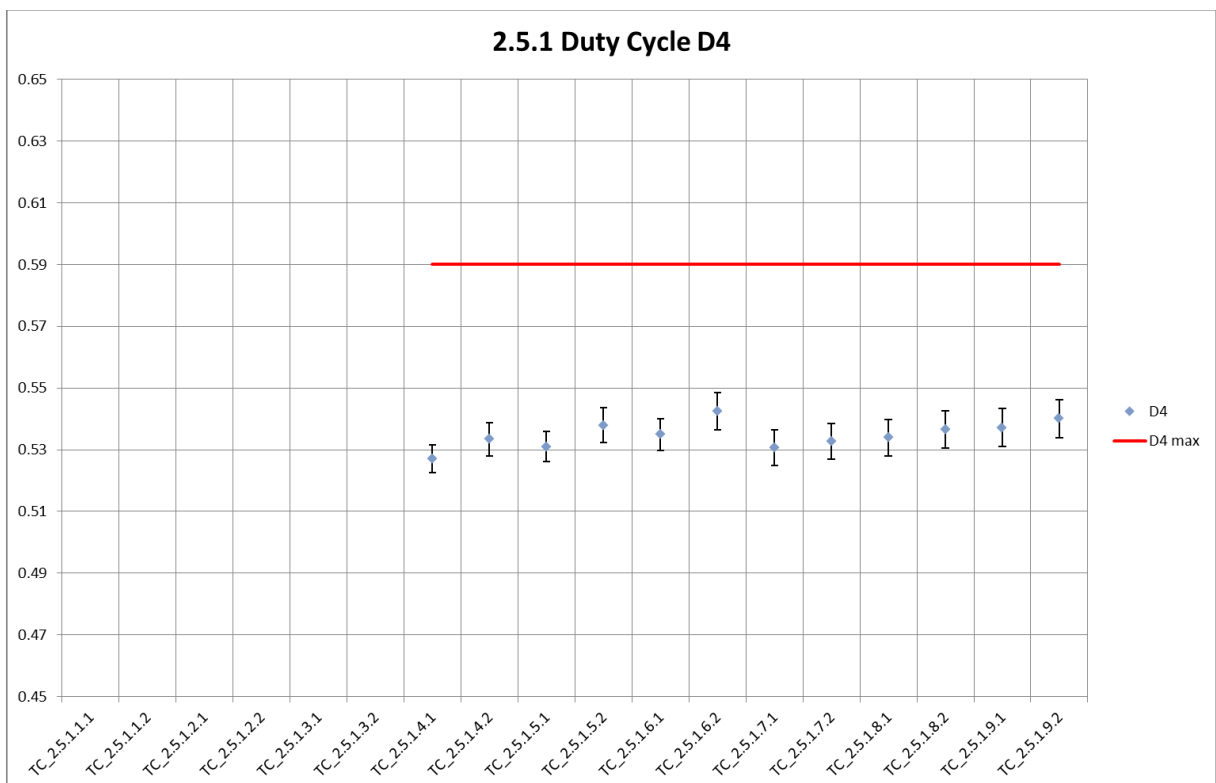
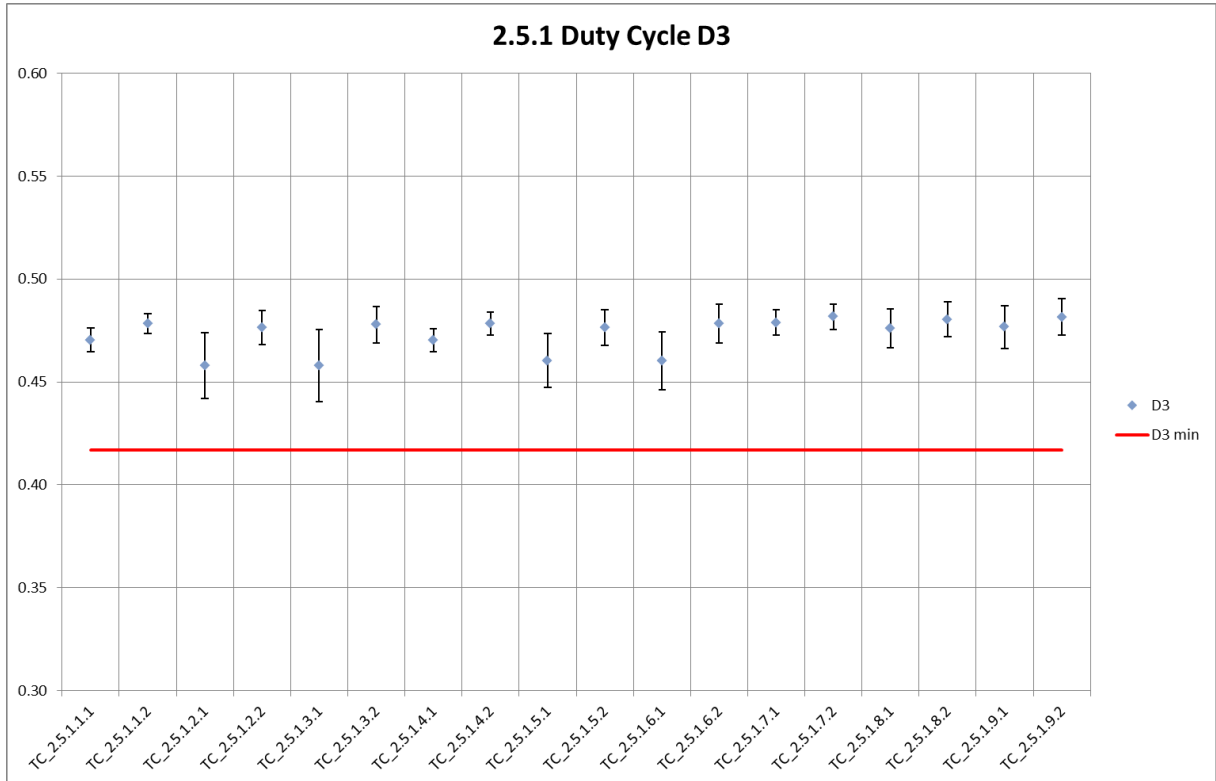


Comment	Test Result
The maximum value of voltage drop shall be less or equal 20mV.	Pass

TC 2.5 *Slope Control*

Sense of this test is checking the slope control function of the driver stage.

TC 2.5.1 Measuring the Duty Cycle @ 10.4 kBit/sec – IUT as Transmitter



Test case #	V _{SUP} / V _{BAT} (PS 1)	V _{PS2} (PS 2)	Bus loads (C; R)	Duty cycle		Result
				D3 ±U*	D4 ±U*	
2.5.1.1.1	7.0V / 8.0V	6.0V	1nF (1%); 1kΩ (0.1%)	0.470 ±0.006	–	Pass
2.5.1.1.2	7.0V / 8.0V	6.6V	1nF (1%); 1kΩ (0.1%)	0.478 ±0.005	–	Pass
2.5.1.2.1	7.0V / 8.0V	6.0V	6.8nF (1%); 660 Ω (0.1%)	0.458 ±0.016	–	Pass
2.5.1.2.2	7.0V / 8.0V	6.6V	6.8nF (1%); 660 Ω (0.1%)	0.476 ±0.008	–	Pass
2.5.1.3.1	7.0V / 8.0V	6.0V	10nF (1%); 500 Ω (0.1%)	0.458 ±0.018	–	Pass
2.5.1.3.2	7.0V / 8.0V	6.6V	10nF (1%); 500 Ω (0.1%)	0.478 ±0.009	–	Pass
2.5.1.4.1	7.6V / 8.6V	6.6V	1nF (1%); 1kΩ (0.1%)	0.470 ±0.006	0.527 ±0.005	Pass
2.5.1.4.2	7.6V / 8.6V	7.2V	1nF (1%); 1kΩ (0.1%)	0.478 ±0.006	0.533 ±0.005	Pass
2.5.1.5.1	7.6V / 8.6V	6.6V	6.8nF (1%); 660 Ω (0.1%)	0.460 ±0.013	0.531 ±0.005	Pass
2.5.1.5.2	7.6V / 8.6V	7.2V	6.8nF (1%); 660 Ω (0.1%)	0.476 ±0.009	0.538 ±0.006	Pass
2.5.1.6.1	7.6V / 8.6V	6.6V	10nF (1%); 500 Ω (0.1%)	0.460 ±0.014	0.535 ±0.005	Pass
2.5.1.6.2	7.6V / 8.6V	7.2V	10nF (1%); 500 Ω (0.1%)	0.478 ±0.009	0.542 ±0.006	Pass
2.5.1.7.1	18V / 18.6V	17.0V	1nF (1%); 1kΩ (0.1%)	0.479 ±0.006	0.531 ±0.006	Pass
2.5.1.7.2	18V / 18.6V	17.6V	1nF (1%); 1kΩ (0.1%)	0.482 ±0.006	0.533 ±0.006	Pass
2.5.1.8.1	18V / 18.6V	17.0V	6.8nF (1%); 660 Ω (0.1%)	0.476 ±0.009	0.534 ±0.006	Pass
2.5.1.8.2	18V / 18.6V	17.6V	6.8nF (1%); 660 Ω (0.1%)	0.480 ±0.008	0.537 ±0.006	Pass
2.5.1.9.1	18V / 18.6V	17.0V	10nF (1%); 500 Ω (0.1%)	0.477 ±0.010	0.537 ±0.006	Pass
2.5.1.9.2	18V / 18.6V	17.6V	10nF (1%); 500 Ω (0.1%)	0.482 ±0.009	0.540 ±0.006	Pass

*The measurement uncertainty analysis based on the type B evaluation according to the “Guide to the Expression of Uncertainty in Measurement” (European Committee for Standardization, ENV 13005, 1999).

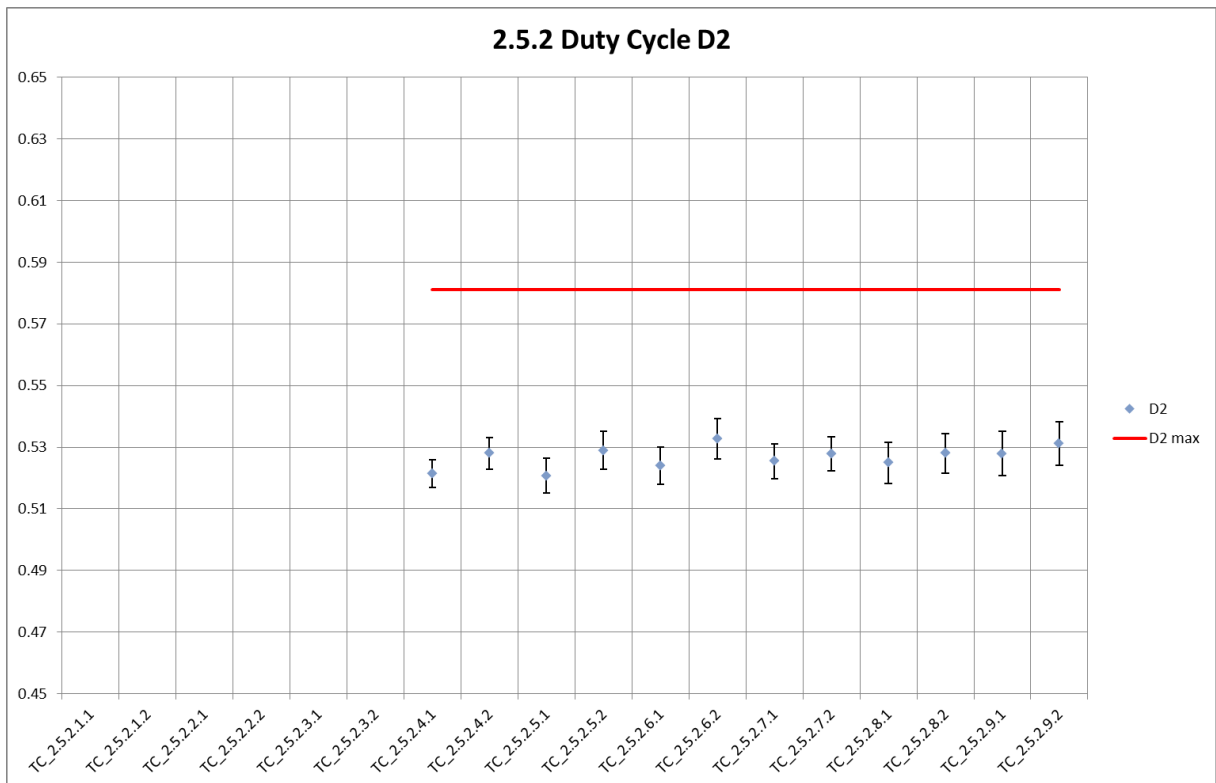
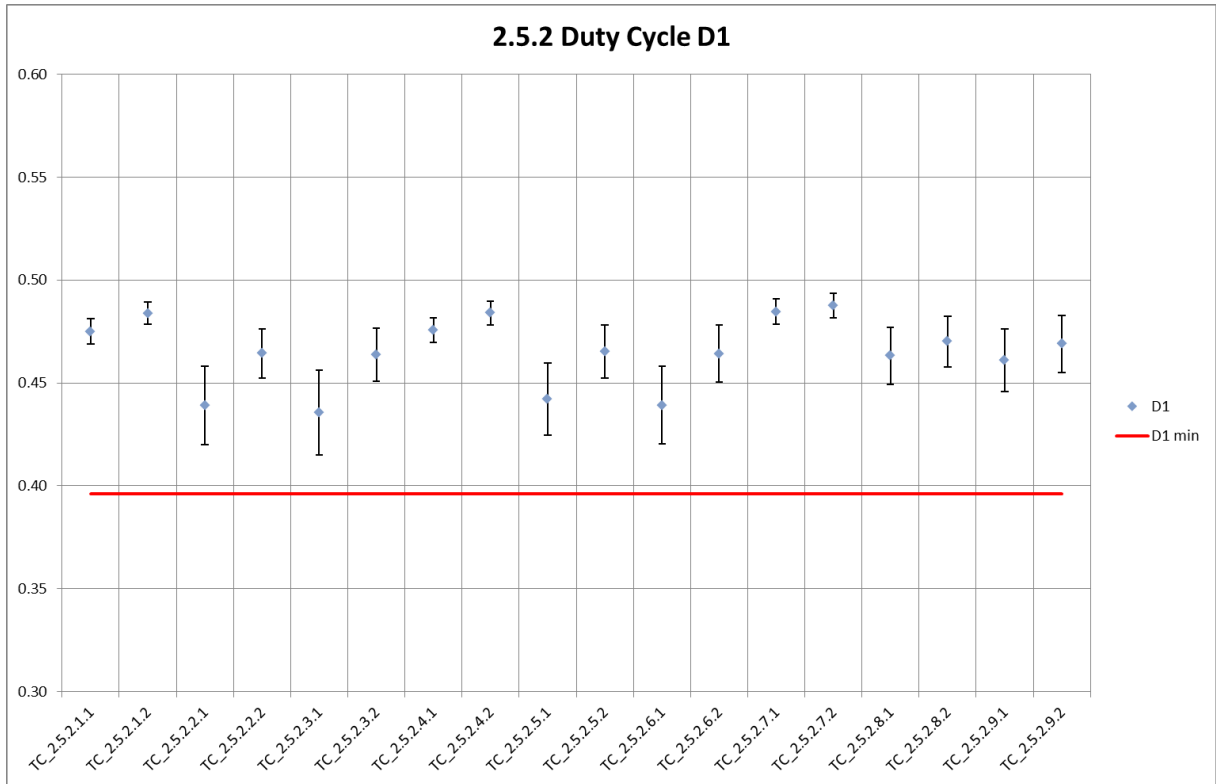
The steps involved are as follows:

1. Evaluation of the relationship between input quantities x_i and the output quantity $y = f(x_1, x_2, \dots, x_n)$
2. Identification of the standard uncertainty $u(x_i)$ for each input estimate x_i

3. Identification of the combined standard uncertainty $u_c(x_i)$ for the output quantity y
4. Calculation of the expanded uncertainty $U = k \cdot u_c(x_i)$, with coverage factor $k=2$. The coverage probability is approximately 95%.

Comment	Test Result
The measured duty cycle D3 must be greater or equal than 0.417 for $V_{SUP} = [7.0V... 18V]$, the measured duty cycle D4 must also be less or equal than 0.590 for $V_{SUP} = [7.6V... 18V]$.	Pass

TC 2.5.2 Measuring the Duty Cycle @ 20 kBit/sec – IUT as Transmitter



Test case #	V _{SUP} / V _{BAT} (PS 1)	V _{PS2} (PS 2)	Bus loads (C; R)	Duty cycle		Result
				D1±U*	D2±U*	
2.5.2.1.1	7.0V / 8.0V	6.0V	1nF (1%); 1kΩ (0.1%)	0.475 ±0.006	–	Pass
2.5.2.1.2	7.0V / 8.0V	6.6V	1nF (1%); 1kΩ (0.1%)	0.484 ±0.005	–	Pass
2.5.2.2.1	7.0V / 8.0V	6.0V	6.8nF (1%); 660 Ω (0.1%)	0.439 ±0.019	–	Pass
2.5.2.2.2	7.0V / 8.0V	6.6V	6.8nF (1%); 660 Ω (0.1%)	0.464 ±0.012	–	Pass
2.5.2.3.1	7.0V / 8.0V	6.0V	10nF (1%); 500 Ω (0.1%)	0.436 ±0.021	–	Pass
2.5.2.3.2	7.0V / 8.0V	6.6V	10nF (1%); 500 Ω (0.1%)	0.464 ±0.013	–	Pass
2.5.2.4.1	7.6V / 8.6V	6.6V	1nF (1%); 1kΩ (0.1%)	0.476 ±0.006	0.521 ±0.004	Pass
2.5.2.4.2	7.6V / 8.6V	7.2V	1nF (1%); 1kΩ (0.1%)	0.484 ±0.006	0.528 ±0.005	Pass
2.5.2.5.1	7.6V / 8.6V	6.6V	6.8nF (1%); 660 Ω (0.1%)	0.442 ±0.017	0.521 ±0.006	Pass
2.5.2.5.2	7.6V / 8.6V	7.2V	6.8nF (1%); 660 Ω (0.1%)	0.465 ±0.013	0.529 ±0.006	Pass
2.5.2.6.1	7.6V / 8.6V	6.6V	10nF (1%); 500 Ω (0.1%)	0.439 ±0.019	0.524 ±0.006	Pass
2.5.2.6.2	7.6V / 8.6V	7.2V	10nF (1%); 500 Ω (0.1%)	0.464 ±0.014	0.533 ±0.007	Pass
2.5.2.7.1	18V / 18.6V	17.0V	1nF (1%); 1kΩ (0.1%)	0.485 ±0.006	0.525 ±0.006	Pass
2.5.2.7.2	18V / 18.6V	17.6V	1nF (1%); 1kΩ (0.1%)	0.488 ±0.006	0.528 ±0.005	Pass
2.5.2.8.1	18V / 18.6V	17.0V	6.8nF (1%); 660 Ω (0.1%)	0.463 ±0.014	0.525 ±0.007	Pass
2.5.2.8.2	18V / 18.6V	17.6V	6.8nF (1%); 660 Ω (0.1%)	0.470 ±0.012	0.528 ±0.006	Pass
2.5.2.9.1	18V / 18.6V	17.0V	10nF (1%); 500 Ω (0.1%)	0.461 ±0.015	0.528 ±0.007	Pass
2.5.2.9.2	18V / 18.6V	17.6V	10nF (1%); 500 Ω (0.1%)	0.469 ±0.014	0.531 ±0.007	Pass

*The measurement uncertainty analysis based on the type B evaluation according to the “Guide to the Expression of Uncertainty in Measurement” (European Committee for Standardization, ENV 13005, 1999).

The steps involved are as follows:

1. Evaluation of the relationship between input quantities x_i and the output quantity $y = f(x_1, x_2, \dots, x_n)$
2. Identification of the standard uncertainty $u(x_i)$ for each input estimate x_i

3. Identification of the combined standard uncertainty $u_c(x_i)$ for the output quantity y
4. Calculation of the expanded uncertainty $U = k \cdot u_c(x_i)$, with coverage factor $k=2$. The coverage probability is approximately 95%.

Comment	Test Result
The measured duty cycle D1 must be greater or equal than 0.396 for $V_{SUP} = [7.0V - 18V]$, the measured duty cycle D2 must be less or equal than 0.581 for $V_{SUP} = [7.6V - 18V]$.	Pass

TC 2.6 Propagation Delay

TC 2.6.1 Propagation Delay of the Receiver

The following test checks the receiver internal delay and its symmetry.

TC	V _{SUP}	RX Load	t _{rx_pdr}	t _{rx_pdr}	t _{rx_pd}	t _{rx_sym}
2.6.1.1	7V	20pF	2.765 μs	2.730 μs	2.765 μs	0.035 μs
2.6.1.2	14V	20pF	2.690 μs	2.700 μs	2.700 μs	-0.010 μs
2.6.1.3	18V	20pF	2.700 μs	2.690 μs	2.700 μs	0.010 μs

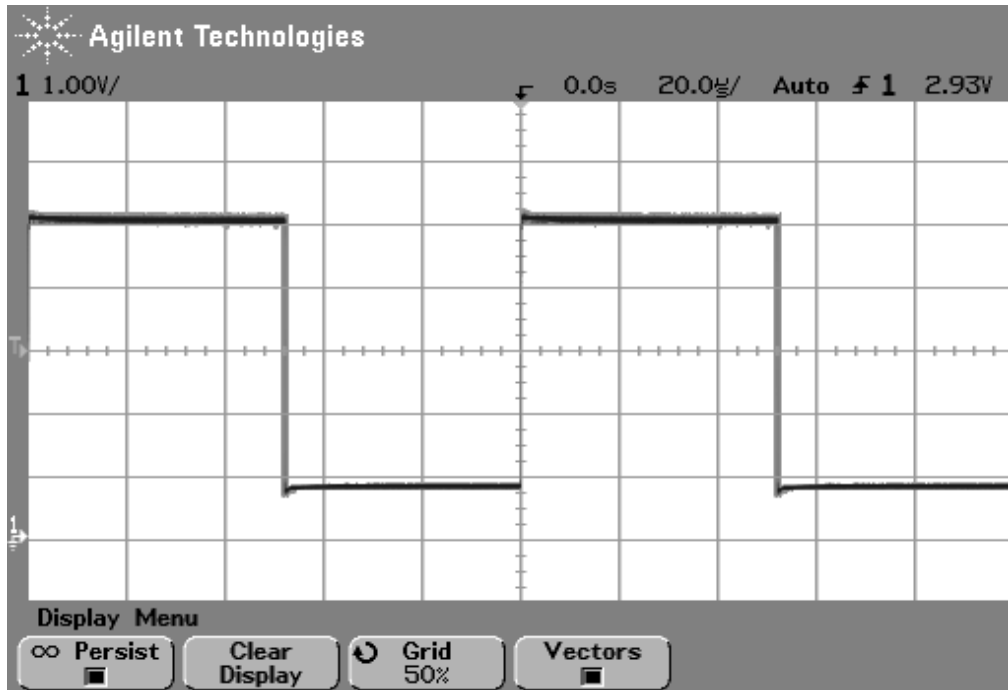
Comment	Test Result
The measured time t _{rx_pd} is less than 6μs, the symmetry t _{rx_sym} is in range of ± 2μs	Pass

TC 2.7

GND/V_{BAT} Shift Test – Dynamic

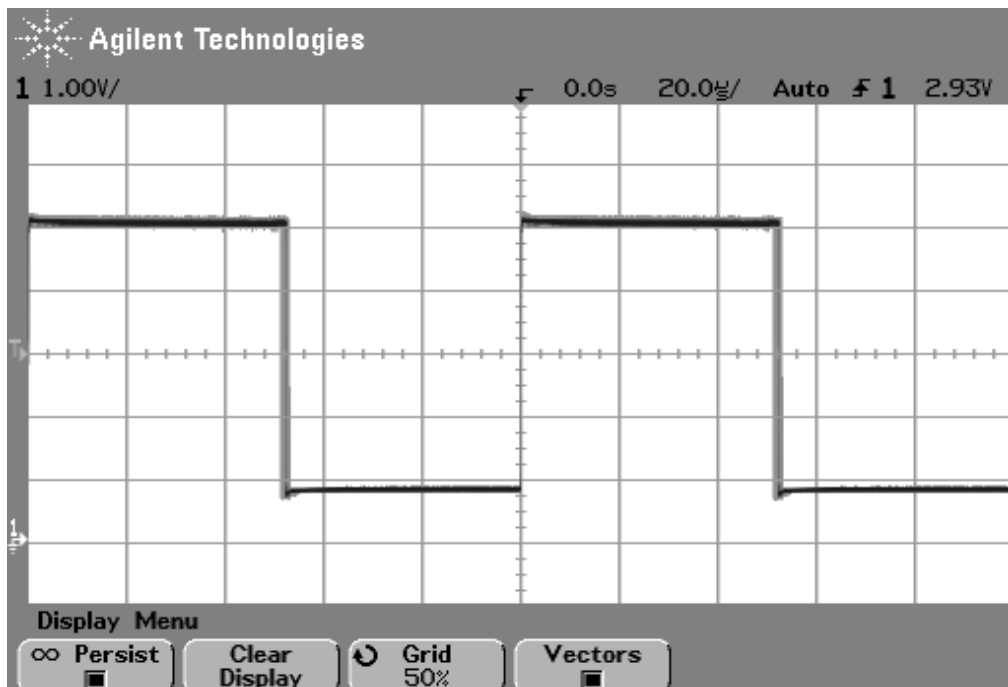
TC 2.7.1

GND Shift Test – Dynamic - IUT as Transceiver (Master)



1kΩ/1nF

Duty Cycle in range of 51.6% – 52.8%

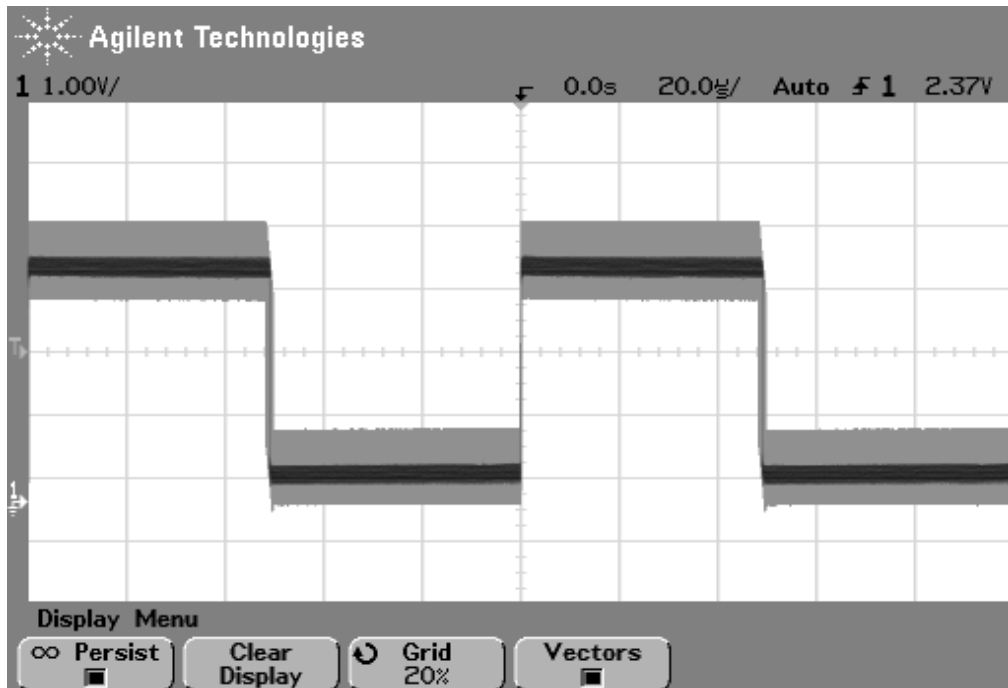


500Ω/10nF

Duty Cycle in range of 51.4% – 53.0%

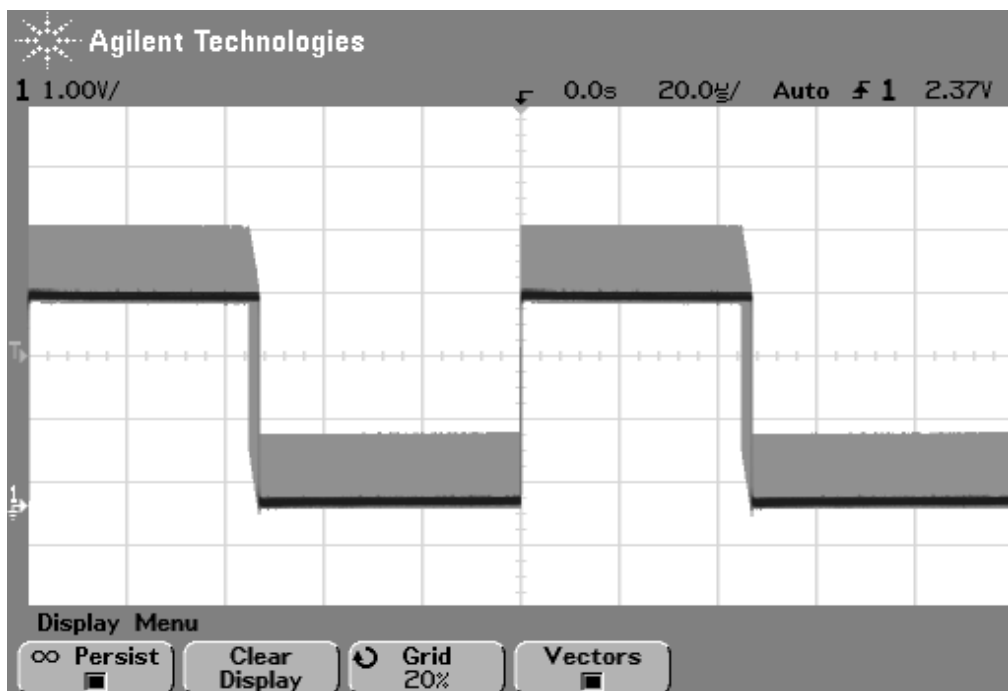
Comment	Test Result
The receive duty cycle measured at RxD2 must be in the range of 0.376 ... 0.601.	Pass

TC 2.7.2 GND Shift Test – Dynamic - IUT as Transceiver (Slave)



1kΩ/1nF

Duty Cycle in range of 48.2% – 49.7%

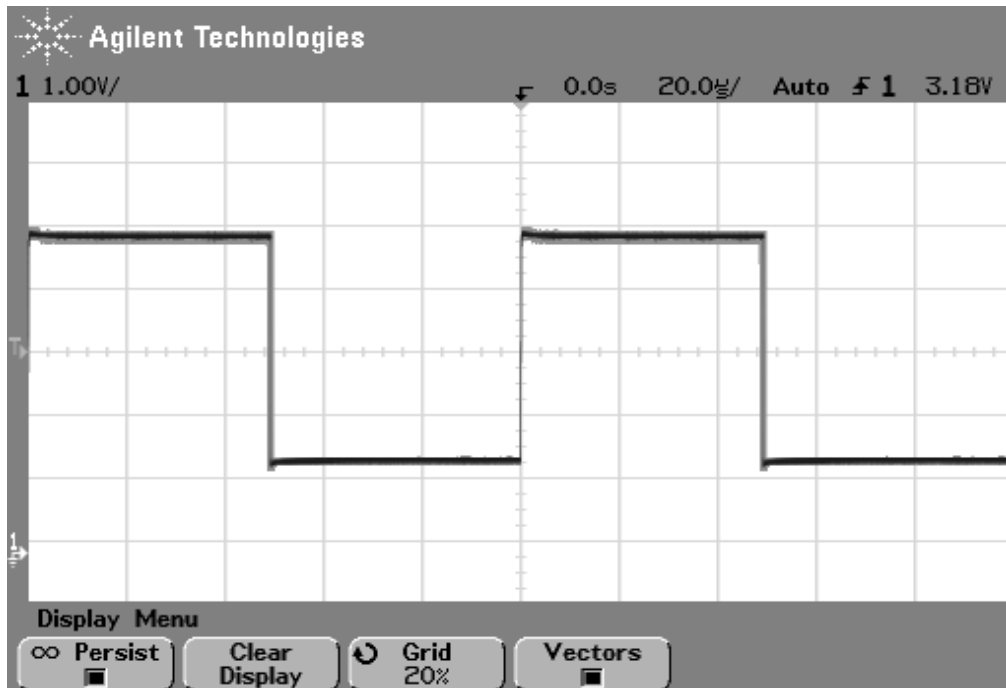


500Ω/10nF

Duty Cycle in range of 44.8% – 47.0%

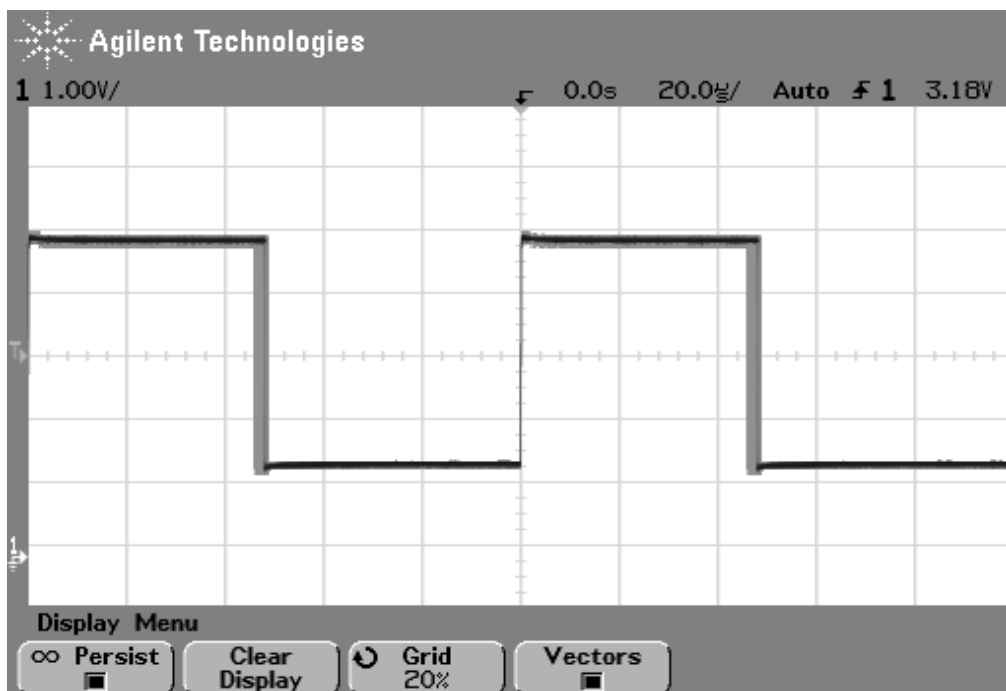
Comment	Test Result
The receive duty cycle measured at RxD2 must be in the range of 0.376 ... 0.601.	Pass

TC 2.7.3 V_{BAT} Shift Test – Dynamic - IUT as Transceiver (Master)



1k Ω /1nF

Duty Cycle in range of 48.7% – 49.8%

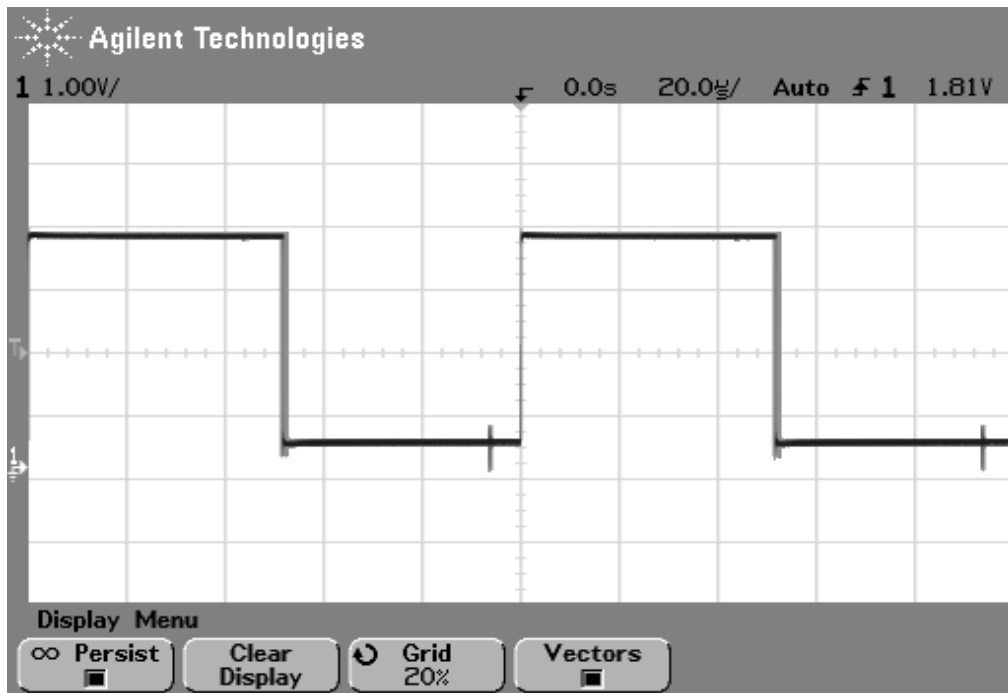


500 Ω /10nF

Duty Cycle in range of 45.9% – 48.8%

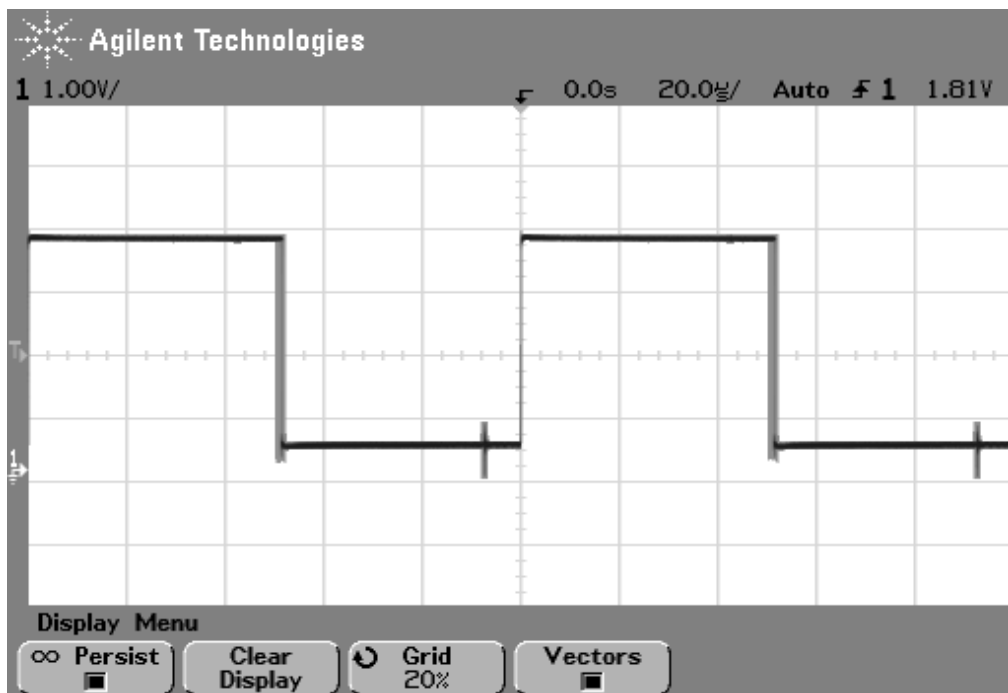
Comment	Test Result
The receive duty cycle measured at RxD2 must be in the range of 0.376 ... 0.601.	Pass

TC 2.7.4 V_{BAT} Shift Test – Dynamic - IUT as Transceiver (Slave)



1kΩ/1nF

Duty Cycle in range of 51.3% – 52.7%



500Ω/10nF

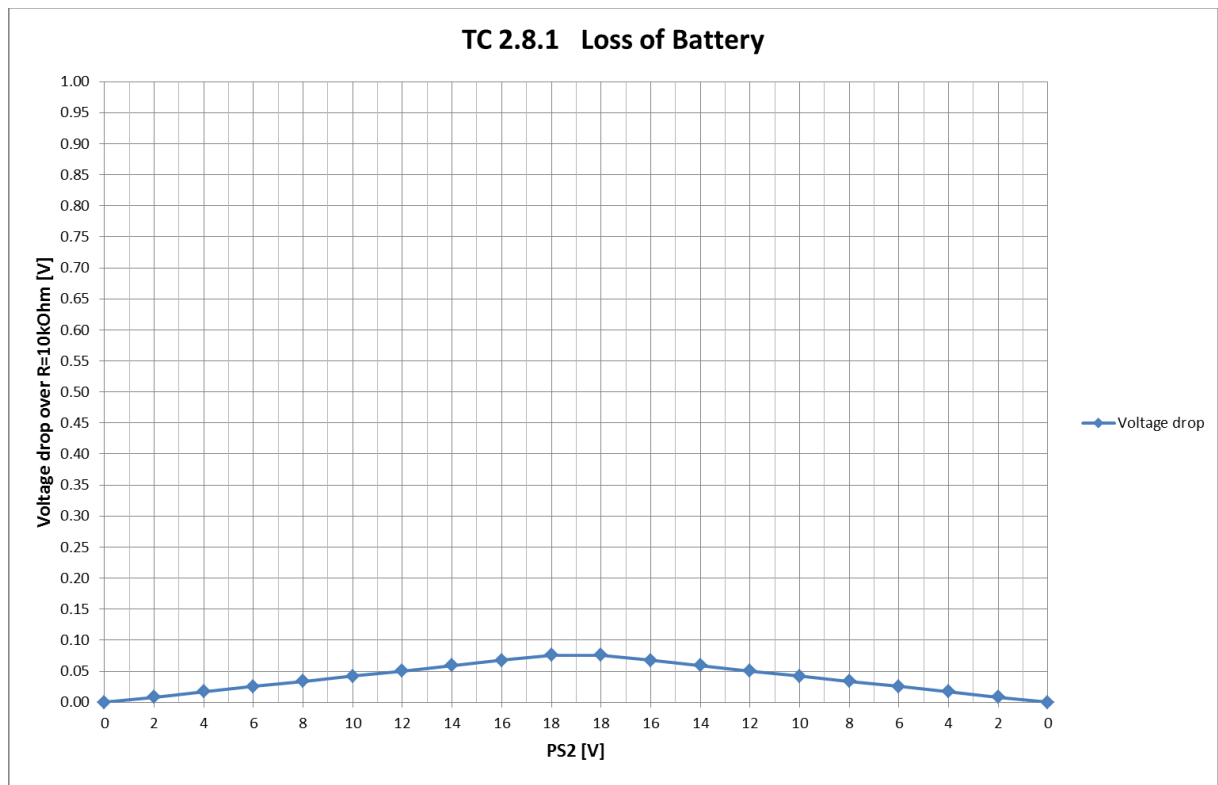
Duty Cycle in range of 50.3% – 52.1%

Comment	Test Result
The receive duty cycle measured at RxD2 must be in the range of 0.376 ... 0.601.	Pass

TC 2.8 *Failure*

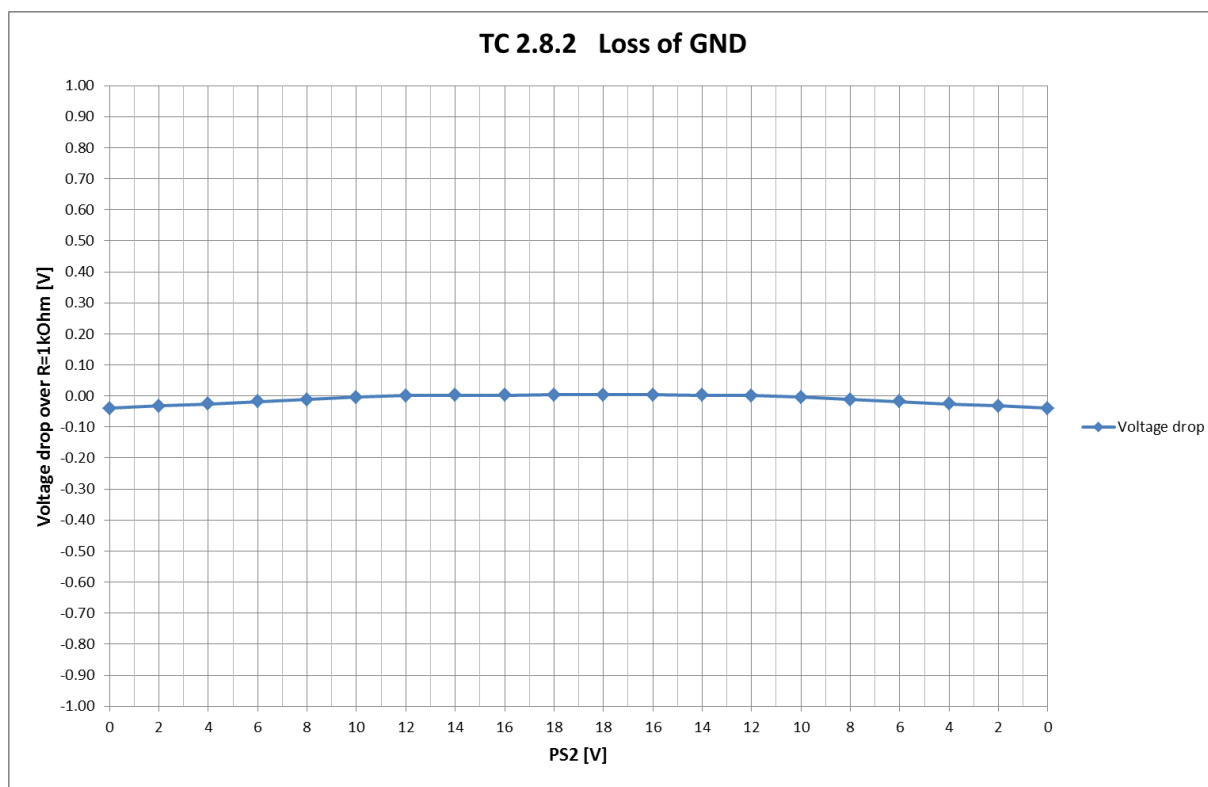
Purpose of this test is to check, whether some parasitic reverse currents are flowing into the IUT.

TC 2.8.1 *Loss of Battery*



Comment	Test Result
I_{BUS} must be less than $100\mu A$, means 1V voltage drop over $R=10k\Omega$. After reconnecting battery line, IUT must restart after failure recovery.	Pass

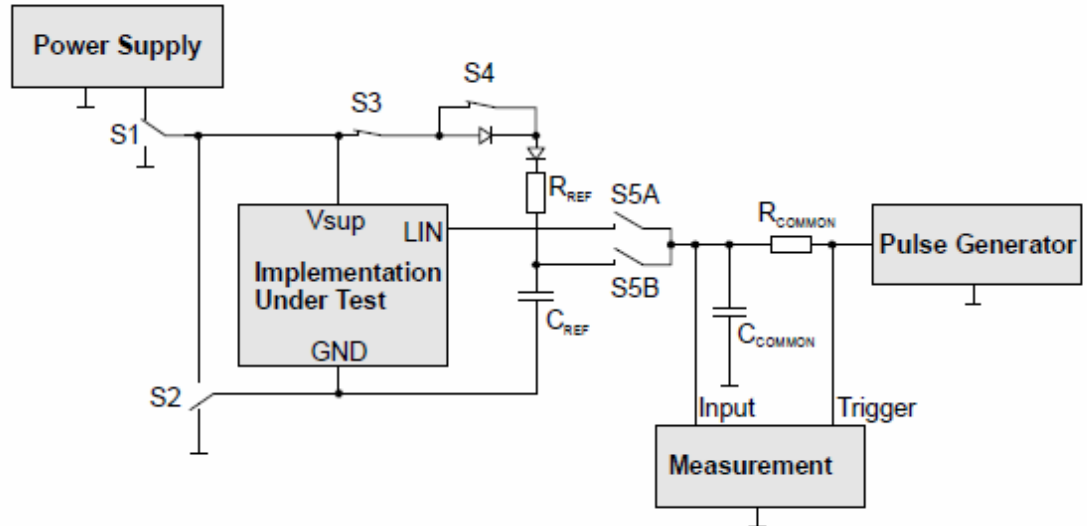
TC 2.8.2 Loss of GND



Comment	Test Result
I_{BUS} must be included in $\pm 1\text{mA}$, means 1V voltage drop over $R=1\text{kOhm}$.	Pass

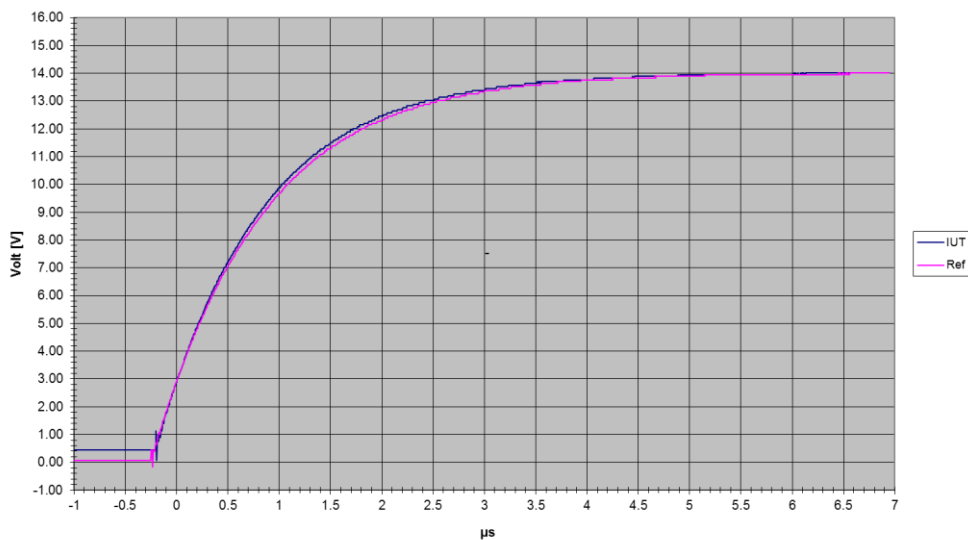
TC 2.9 Verifying internal capacitance and dynamic interference – IUT as Slave

Test Configuration:



TC 2.9.1 Normal power supply

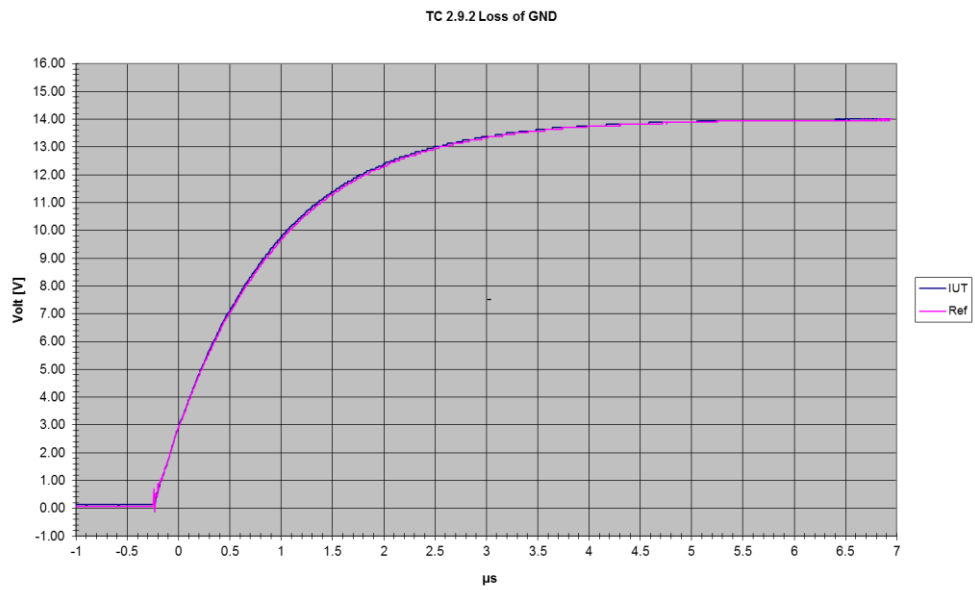
TC 2.9.1 Normal power supply



T_{INT}	T_{REF}
1.015 μ s	1.060 μ s

Comment	Test Result
<p>C_{SLAVE} must be less or equal than 250pF: $T_{INT} \leq T_{REF}$</p> <p>The IUT must not interfere with the dynamic stimulus.</p>	Pass

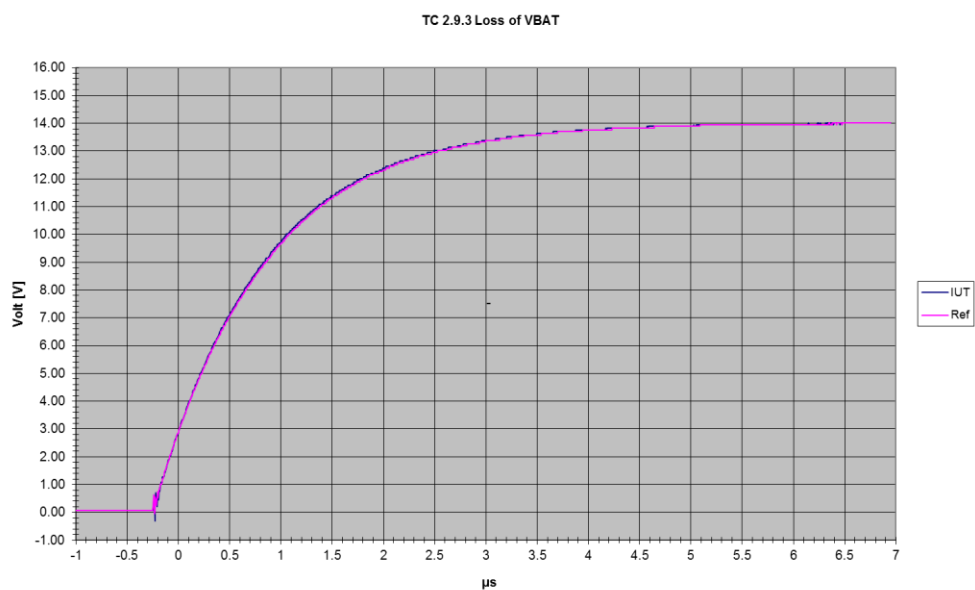
TC 2.9.2 IUT loss of GND



T_{INT}	T_{REF}
1.040 μs	1.060 μs

Comment	Test Result
C_{SLAVE} must be less or equal than 250pF: $T_{INT} \leq T_{REF}$ The IUT must not interfere with the dynamic stimulus.	Pass

TC 2.9.3 IUT loss of V_{SUP}



T _{INT}	T _{REF}
1.040 μs	1.060 μs

Comment	Test Result
C _{SLAVE} must be less or equal than 250pF: T _{INT} ≤ T _{REF} The IUT must not interfere with the dynamic stimulus.	Pass